

# INFLUENCES OF LITHIUM/CAESIUM ADDITIONAL/SUBSTITUTIONAL DOPING ON PHASE FORMATION, MICROSTRUCTURE AND ELECTRICAL PROPERTIES OF (K<sub>0.5</sub>NA<sub>0.5</sub>)(NB<sub>0.7</sub>TA<sub>0.3</sub>)O<sub>3</sub> CERAMICS



A Thesis Submitted to the Graduate School of Naresuan University in Partial Fulfillment of the Requirements for the Doctor of Philosophy in Applied Physics - (Type 1.1) 2021

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has been approved by the Graduate School as partial fulfillment of the requirements for the Doctor of Philosophy in Applied Physics - (Type 1.1) of Naresuan University

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Title	INFLUENCES OF LITHIUM/CAESIUM
	ADDITIONAL/SUBSTITUTIONAL DOPING ON
	PHASE FORMATION, MICROSTRUCTURE AND
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	(K <sub>0.5</sub> NA <sub>0.5</sub> )(NB <sub>0.7</sub> TA <sub>0.3</sub> )O <sub>3</sub> CERAMICS
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Academic Paper	Assistant Professor Sasipohn Prasertpalichat, Ph.D. Ph.D. Dissertation in Applied Physics - (Type 1.1),
	Naresuan University, 2021
Keywords	KNNT, Phase formation, Rietveld refinement, Electrical
	properties, Solid-state combusition method

## ABSTRACT

The effect of the firing conditions on the phase formation, microstructure, and electrical properties of (K<sub>0.5</sub>Na<sub>0.5</sub>)(Nb<sub>0.7</sub>Ta<sub>0.3</sub>)O<sub>3</sub> (KNNT) ceramics synthesized by the solid-state combustion technique using glycine as fuel has been investigated. All samples were calcined at 600 to 800°C for 2 h and sintered at 1150 to 1190°C for 2 to 5 h. Pure KNNT powders were produced after calcination at 600°C for 2 h. The average particle size increased when the calcination temperature was increased. The KNNT powder calcined at 600°C for 2 h showed rather square morphology with average particle size of  $\sim 160 \text{ nm}$ . The x-ray diffraction (XRD) analysis results for the ceramics revealed the presence of orthorhombic (O) and tetragonal (T) phases in all samples. When sintering at 1150°C for 4 h, the O:T ratio was 50:50, as verified by the Rietveld refinement technique. The average grain size, density values, and dielectric properties tended to increase when the dwell time was increased from 2 to 4 h, but then degraded. The KNNT ceramic produced at the optimum firing condition (1150°C for 4 h) showed good crystalline morphology, the highest density ( $\rho = 5.28 \text{ g/cm}^3$ ), the highest dielectric constant ( $\varepsilon_{\rm C} = 5002$ ), and good ferroelectric behavior ( $P_{\rm r} = 18.50$  $\mu$ C/cm<sup>2</sup> and  $E_c = 9.04 k$ V/cm).

Then, the effects of Cs<sup>+</sup> substitution and direct doping in

 $(K_{0.5}Na_{0.5})(Nb_{0.7}Ta_{0.3})O_3$  (KNNT) ceramics, on the crystal structure, microstructure and electrical properties were investigated. Both the KNNT with Cs<sup>+</sup> substitution  $(K_{0.5-x}Cs_xNNT)$  and addition (KNNT-xCs) (x=0, 0.01, 0.02, 0.03 and 0.04 mol.%) were synthesized by the solid-state combustion technique using glycine as fuel. All samples were sintered at 1130-1150°C for 4 h. The x-ray diffraction (XRD) analysis for the ceramics revealed the presence of *O* and *T* phases in all samples. Increasing both the Cs<sup>+</sup> substitution and doping amounts, enhanced orthorhombicity, as verified by the Rietveld refinement technique. It was found that Cs<sup>+</sup> doping, either substitutional or additional, strongly decreased their density, dielectric and ferroelectric properties. The undoped KNNT ceramic exhibited well-saturated *P-E* hysteresis loop. With Cs<sup>+</sup> doping, the samples became unsaturated and a leakage current was produced. The KNNT-xCs ceramics demonstrated higher density and dielectric properties than the K<sub>0.5-x</sub>Cs<sub>x</sub>NNT ceramics.

After that, lead-free (K<sub>0.5</sub>Na<sub>0.5</sub>)(Nb<sub>0.7</sub>Ta<sub>0.3</sub>)O<sub>3</sub> (KNNT) ceramics with Li<sup>+</sup> substitution (KN<sub>0.5-x</sub>Li<sub>x</sub>NT) and direct (KNNT-xLi) doping at x=0, 0.01, 0.02, 0.03 and 0.04 mol.% were synthesized by the solid-state combustion route. The phase, microstructure, dielectric and ferroelectric properties of the ceramics were examined. The XRD pattern of the ceramics revealed orthorhombic and tetragonal phases were in all specimens. The Rietveld refinement procedure showed that increasing either the Li<sup>+</sup> substitution or doping levels enhanced the amount of the tetragonal phase. It was found that Li<sup>+</sup> doping, either substitutional or additional, enhanced the Curie temperature (*T*<sub>C</sub>) by increasing the tetragonal distortion, while the dielectric constant ( $\varepsilon_{\rm C}$ ) decreased. The good remanent *P-E* loops of the KN<sub>0.5-x</sub>Li<sub>x</sub>NT ceramics was found with x=0.01 (*P*<sub>r</sub>~10.89  $\mu$ C/cm<sup>2</sup> and *E*<sub>C</sub>~13.09 *k*V/cm), while for KNNT-xLi ceramics, it was obtained with x=0.02 (*P*<sub>r</sub>~15.65  $\mu$ C/cm<sup>2</sup> and *E*<sub>C</sub>~11.46 *k*V/cm), which were confirmed by remanent *P-E* hysteresis measurements.

### ACKNOWLEDGEMENTS

I would like to express the deepest gratitude to my advisor, Associate Professor Theerachai Bongkarn, Ph.D, and co-advisor Assistant Professor Sasipohn Prasertpalichat, Ph.D. and Associate Professor Tawat Suriwong, Ph.D, for his initial idea, guidance, and encouragement which enable me to carry out my study successfully. I consider it as a great opportunity to do my doctoral program under his advice and to learn from his research expertise.

My sincere gratitude also goes to my thesis committee, Associate Professor Orawan Ritthidech, Ph.D, and Assistant Professor Jaru Jutimoosik, Ph.D. for their helpful advice, comments and suggestions.

My profound thanks to Department of Physics, Faculty of Science, Naresuan University for being warmest places to study since the researcher studied a Bachelor's degree and Doctoral degree here. I feel love and commitment with here. I would like to thank Science Lab Center and Miss Thanita Sutthatang for XRD analysis, Mr. Seangphet Boonpang and Miss Prakaithip Kitikhun for from SEM analysis for their assistance in the part of instrument.

I would like to acknowledge the Science Achievement Scholarships of Thailand (SAST) Ph.D. Program to Miss Surirat Yotthuan all financial support during this study.

Finally, I would like to thank my family for their love and their understanding. They have been constantly providing me with encouragement, enjoyment during my life and enabled me to complete this thesis.

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## **CHAPTER I**

## **INTRODUCTION**

#### Overview

Since the 1650s, the (PbZr<sub>1-x</sub>Ti<sub>x</sub>O<sub>3</sub>, PZT)-based materials have been given extremely interest owing to their outstanding piezoelectric constants ( $d_{33}$ ~200-750 pC/N) and high Curie temperatures ( $T_{C}$ ~180-320°C) and are presently applied in many electronic devices (e.g., multilayer ceramic capacitors, sensors, actuators, ultrasonic transducers, energy harvesters, and so on) (1-4). Nevertheless, the element of lead (Pb) is dangerous, and high levels (>60 wt.%) of Pb content in the PZT-based ceramics generate great threat to the environmental and human health, including the use of hazardous chemicals in electronic devices has been increasingly banned by laws and regulations (1-4). As a result, scientists have focused their utmost efforts on the development of lead-free replacements. Among various without lead materials (5-7), sodium potassium niobate (K,Na)NbO<sub>3</sub> (KNN) ceramics, the solid solution of ferroelectric KNbO<sub>3</sub> and antiferroelectric NaNbO<sub>3</sub>, are one good contestant for leadfree ceramics owing to its great piezoelectric coefficient  $(d_{33})$ , high Curie temperature  $(T_{\rm C})$ , large electromechanical coupling factor  $(k_{\rm p})$  and environmentally friendly chemical composition (8). Unfortunately, a few shortcomings, e.g., poor ferroelectric properties (existing leakage current) and low dielectric constant ( $\varepsilon$ ), still preclude huge industrial applications of KNN-based ceramics on account of poor sintering and low density caused by the fluctuation of K<sub>2</sub>O and Na<sub>2</sub>O compounds at high temperatures. Li et al. (9) synthesized the lead-free K<sub>0.5</sub>Na<sub>0.5</sub>Nb<sub>0.7</sub>Ta<sub>0.3</sub>O<sub>3</sub> (KNNT) ceramic using a novel hydro/solvothermal technique. The ceramics exhibited coexistence of orthorhombic and tetragonal phases and showed high density ( $\rho \sim$ 93.82%). After that, Lv et al. (10) fabricated KNNT ceramic using the solid-state reaction technique (with calcination at 900°C for 5 h and sintering at 1170°C for 2 h). The samples showed high  $\rho$  (~94.40%), dielectric constant at  $T_{\rm C}$  ( $\varepsilon_{\rm C}$ ~6,000) and  $T_{\rm C}$ (~230°C).

Recently, many studies proved that improvement in the density and electric properties of lead-free materials can be accomplished by adding and/or substituting with a small number of other elements or compounds, such as CoO, CuO, CrO, Fe<sub>2</sub>O<sub>3</sub>, In<sub>2</sub>O<sub>3</sub> Li<sub>2</sub>CO<sub>3</sub>, MnO, and NiO (11-19). For the direct doping of element in KNN-based ceramics, J. Liu et al. (12) reported that direct doping with Cu<sup>2+</sup> at an amount of 0.01 mol.% into 0.98K<sub>0.5</sub>Na<sub>0.5</sub>NbO<sub>3</sub>-0.02BiScO<sub>3</sub> ceramics enhanced the p (~4.6 g/cm<sup>3</sup>),  $\varepsilon_{\rm C}$  (~5500) and  $d_{33}$  (~207 pC/N). In 2016, the maximum  $\varepsilon_{\rm C}$  (~7520),  $(P_{\rm r} \sim 27.9 \ \mu {\rm C/cm^2})$ and  $d_{33}$ (~311 remnant polarization pC/N) of (K<sub>0.44</sub>Na<sub>0.52</sub>Li<sub>0.04</sub>)(Nb<sub>0.84</sub>Ta<sub>0.10</sub>Sb<sub>0.06</sub>)O<sub>3</sub> ceramics were obtained from additional doping Fe<sup>3+</sup> at 0.6 wt.%, as announced by T. Bongkarn et al. (14). Next, Y. Zhao et al. (15) observed that additional doping of 1 mol%  $In^{3+}$  into KNN ceramics could improve  $P_r \sim 31.52 \ \mu C/cm^2$  compared with the undoped ceramics. In that instance of the substitution doping in KNN-based ceramics, C. Long et al. (16) suggested that substitutional doping of Na<sup>+</sup> and K<sup>+</sup> by 0.06 mol.% Li<sup>+</sup> in A-sites of  $(Na_{0.5}K_{0.5})_{0.94}Li_{0.06}NbO_3$  ceramics can enhanced the  $T_c$  (~473°C),  $P_r$  (~29  $\mu$ C/cm<sup>2</sup>) and  $(S_{33} \sim 0.152\%).$ large field-induced strain Similarly, the modified 0.96(K<sub>0.48</sub>Na<sub>0.49</sub>Li<sub>0.03</sub>)NbO<sub>3</sub>-0.04Bi<sub>0.5</sub>Na<sub>0.5</sub>ZrO<sub>3</sub> ceramic with Li<sup>+</sup> doping at 0.03 mol.% exhibit a highest the dielectric constant at room temperature ( $\varepsilon_R \sim 1300$ ),  $\varepsilon_C$ (~5,000) and large  $d_{33}$  (~252 pC/N) (17). On the other hand, various kinds of doping would produce sophisticated influences on the phase evolution, microstructure and electrical behaviors of ceramics, since they have a different valence, ionic size, and doping sites (20). The different valence of the doping ions (acceptor or donor doping) creates of oxygen vacancies and sophisticated flaws, resulting to pinned ferroelectric domain walls and worsening in electrical behaviors of samples (21). Hence, inspection the effects of the ionic size on the phase structure, microstructure and electrical behaviors for the lead-free ceramics without the influence of valence fluctuation is very compelling. In this work, Cs<sup>+</sup> and Li<sup>+</sup> are appraised because of its ionic radius (Cs<sup>+</sup>~1.88 Å) larger and (Li<sup>+</sup>~1.15 Å) smaller than the ionic radius of both  $K^+$  (~1.64 Å) and Na<sup>+</sup> (~1.39 Å) (16).

So, in this present work, we study the influence of  $Cs^+$  and  $Li^+$  substitutional  $[(K_{0.5-x}Cs_xNa_{0.5}Nb_{0.7}Ta_{0.3}O_3)$  and  $(K_{0.5}Na_{0.5-x}Li_xNb_{0.7}Ta_{0.3}O_3)]$  and additional

 $[(K_{0.5}Na_{0.5}Nb_{0.7}Ta_{0.3}O_3-xmol\%Cs)$  and  $(K_{0.5}Na_{0.5}Nb_{0.7}Ta_{0.3}O_3-xmol.\%Li)]$  doping (x=0, 0.01, 0.02, 0.03 and 0.04 mol.%) on the crystalline phases, microstructure and electrical behaviors of  $K_{0.5}Na_{0.5}Nb_{0.7}Ta_{0.3}O_3$  ceramics synthesized by the solid-state combustion technique.

#### **Research objectives**

1. To study the preparation  $(K_{0.5}Na_{0.5})(Nb_{0.7}Ta_{0.3})O_3$  ceramics with various firing conditions using the solid-state combustion method.

2. To study the preparation  $(K_{0.5}Na_{0.5})(Nb_{0.7}Ta_{0.3})O_3$  ceramics with Cs<sup>+</sup> and Li<sup>+</sup> substitutional and additional doping using the solid-state combustion technique.

3. To inspect the influences of calcination and sintering temperatures on the phase structure, microstructure and electrical properties of  $(K_{0.5}Na_{0.5})(Nb_{0.7}Ta_{0.3})O_3$  ceramics.

4. To inspect the effects of  $Li^+$  and  $Cs^+$  substitutional and additional doping on the phase structure, microstructure and electrical properties of  $(K_{0.5}Na_{0.5})(Nb_{0.7}Ta_{0.3})O_3$  ceramics.

5. To inspect the correlation between phase structure, microstructure and electrical properties of  $(K_{0.5}Na_{0.5})(Nb_{0.7}Ta_{0.3})O_3$  ceramics with Cs<sup>+</sup> and Li<sup>+</sup> substitutional and additional doping.

#### **Research expected outputs**

1. To comprehend the preparation of  $(K_{0.5}Na_{0.5})(Nb_{0.7}Ta_{0.3})O_3$  ceramics with various firing conditions using the solid-state combustion method.

2. To comprehend the preparation of  $(K_{0.5}Na_{0.5})(Nb_{0.7}Ta_{0.3})O_3$  ceramics with Cs<sup>+</sup> and Li<sup>+</sup> substitutional and additional doping using the solid-state combustion technique.

3. To comprehend the influences of calcination and sintering temperatures on the phase structure, microstructure and electrical properties of  $(K_{0.5}Na_{0.5})(Nb_{0.7}Ta_{0.3})O_3$  ceramics.

4. To comprehend the effects of  $Li^+$  and  $Cs^+$  substitutional and additional doping on the phase structure, microstructure and electrical properties of  $(K_{0.5}Na_{0.5})(Nb_{0.7}Ta_{0.3})O_3$  ceramics. 5. To comprehend the correlation between phase structure, microstructure and electrical properties of  $(K_{0.5}Na_{0.5})(Nb_{0.7}Ta_{0.3})O_3$  ceramics with Cs<sup>+</sup> and Li<sup>+</sup> substitutional and additional doping.

#### **Research scope**

1. The  $(K_{0.5}Na_{0.5})(Nb_{0.7}Ta_{0.3})O_3$  powder and ceramics were synthesized by the solidstate combustion method. All samples were calcined at 600, 650, 700, 750 and 800°C for 2 h and sintered at 1150, 1160, 1170, 1180 and 1190°C for 2-5 h, respectively.

2. The (K<sub>0.5</sub>Na<sub>0.5</sub>)(Nb<sub>0.7</sub>Ta<sub>0.3</sub>)O<sub>3</sub> samples with Cs<sup>+</sup> substitutional [(K<sub>0.5</sub>-

xCsxNa0.5)(Nb0.7Ta0.3)O3; K0.5-xCsxNNT] and additional [(K0.5Na0.5)(Nb0.7Ta0.3)O3-

 $xCs_2CO_3$ ; KNNT-xCs] doping (x=0, 0.01, 0.02, 0.03 and 0.04 mol.%) were fabricated by the solid-state combustion method at calcination temperature of 600°C for 2 h and sintering temperatures of 1130-1150°C for 4 h, respectively.

3. The (K<sub>0.5</sub>Na<sub>0.5</sub>)(Nb<sub>0.7</sub>Ta<sub>0.3</sub>)O<sub>3</sub> samples with Li<sup>+</sup> substitutional [(K<sub>0.5</sub>Na<sub>0.5</sub>-

 $_xLi_x)(Nb_{0.7}Ta_{0.3})O_3$ ;  $KN_{0.5-x}Li_xNT$ ] and additional [( $K_{0.5}Na_{0.5})(Nb_{0.7}Ta_{0.3})O_3$ - $xLi_2CO_3$ ; KNNT-xLi] doping (x=0, 0.01, 0.02, 0.03 and 0.04 mol.%) were fabricated by the solid-state combustion method at calcination temperature of 600°C for 2 h and sintering temperatures of 1150°C for 4 h.

4. Inspection of the densification by Archimedes method, phase formation by X-ray diffraction (XRD) and Rietveld refinement method, morphology by scanning electron microscopy (SEM) and transmission electron microscopy (TEM), average grain size by linear intercept method, dielectric properties by an inductance capacitance resistance (LCR) meter and ferroelectric hysteresis (P-E) loops by a computer-controlled modified Sawyer-Tower circuit.

### **CHAPTER II**

## **RELATED THEORY AND LITERATURE REVIEW**

#### **Fundamental theory**

#### **Perovskite Structure**

In the year 1839, the first mineral ( $CaTiO_3$ ) with perovskite structure was discovered by Russian mineralogist (Count Lev Alexevich von Perovski) in the Ural Mountains (22-24). The name perovskite represented any compound, which it has the general stoichiometry ABC<sub>3</sub> where an octahedron of C ions surrounded the B ion. The perovskite family consist various types of oxides such as transition metal oxides with the formula ABO<sub>3</sub>. In the ideal ABO<sub>3</sub> formula, A ion is an alkali earth metals or lanthanides with a larger radius, B is a transition metal ion with a small radius, and O is the oxygen ion. Largely, A cations are 1+ or 2+ of charges such as K<sup>+</sup>, Na<sup>+</sup>, Li<sup>+</sup> or Cs<sup>+</sup> and B cations are 4+ or 5+ of charges such as Ti<sup>4+</sup>, Sn<sup>4+</sup>, Nb<sup>5+</sup> or Ta<sup>5+</sup>. For the cubic unit cell of ABO<sub>3</sub> perovskite structure, atom A is occupied at the body center, atom B is occupied at the cube corner position, and oxygen atoms are occupied at the face-centered position, as presented in Figure 1. The 12-fold coordination of A cation and the 6-fold coordination of the B cation (octahedron) cause the stabilization of the perovskite lattice. The ideal perovskite structure was explained by Hines et al. as corner linked BO<sub>6</sub> octahedra with interstitial A cations (22-30). In the ideal cubic model of perovskite, some distortions can result in orthorhombic, rhombohedral, and hexagonal forms (Figure 1.) (30). Figure 2 display Geometric characteristics of the 7 crystal systems and 14 Bravais lattices. The difference of the 7 crystal systems was determined by the lengths of the unit cell edges (a, b and c) and the angles between the edges ( $\alpha, \beta$  and  $\gamma$ ), which collectively known as the lattice parameters (Figure 2.). Nowadays, the perovskite structure has been studied extremely (31-35). Some examples of ceramics with perovskite structure are lead titanate (PbTiO<sub>3</sub>), lead zirconate titanate (PbZr<sub>1-x</sub>Ti<sub>x</sub>O<sub>3</sub>), potassium niobate (KNbO<sub>3</sub>), potassium sodium niobite-based (K<sub>1-x</sub>Na<sub>x</sub>NbO<sub>3</sub>), bismuth sodium titanate-based (Bi<sub>1-x</sub>Na<sub>x</sub>TiO<sub>3</sub>), barium titanate (BaTiO<sub>3</sub>) and so on.



Figure 1 Various types perovskite unit cells. Blue spheres refer to the A cations, yellow spheres refer to the B cations and red spheres refer to oxygen anions

forming an octahedra.



Figure 2 Geometric characteristics of the 7 crystal systems and 14 Bravais lattices.

#### **Ceramic Microstructures**

The both of single crystals and polycrystalline solids contain in crystalline solids. A single crystal is a solid in which the periodic and repeated alignment of atoms is excellent and broadens during the entirety of the samples continuous. A polycrystalline solid is included of a bevy of plenty single crystals, called grains, separated from one another by regions of disorder called grain boundaries, as represented in Figure 3. Normally, in ceramics the grains are in the range of 1 to 50  $\mu$ m and only can be seen under a microscope (35). The microstructure is defined by the shape and size of the grains, existence of porosity, second phases, and other properties, as well as their distribution. Many of the characteristics of ceramics are influenced by their microstructure.



Figure 3 (a) Diagram of a polycrystalline specimen. A polycrystal is consist of numerous grains separated from one another by areas of disorder called grain boundaries and (b) Normal microstructure as seen via an optical microscope.

#### **Ferroelectricity**

Ferroelectricity is a phenomenon illustrate by crystals with a spontaneous polarization and hysteresis effects associated with dielectric changes when an electric field is given (36-38). In the year 1921, the ferroelectricity was first discovered in single-crystal materials of Rochelle salt. After that, throughout the early to mid-1940, its subsequent expansion into the scope of polycrystalline ceramics (i.e., barium titanate, BaTiO<sub>3</sub>). There has been a continuous succession of new materials and technology developments, leading to a significant number of industrial and commercial applications as such high-dielectric-constant capacitors, piezoelectric sonar and ultrasonic transducers, radio and communication filters, pyroelectric security surveillance devices, medical diagnostic transducers, stereo tweeters, buzzers, gas ignitors, positive temperature coefficient (PTC) sensors and switches, ultrasonic motors, electro-optic light valves, thin-film capacitors and FE thin-film memories, etc. (36-38)

Hysteresis Loop

In basis, every ferroelectric material has own characteristic hysteresis loop, just like a fingerprint. The hysteresis loops can be used to identify the ferroelectricity directly. Figure 4 illustrates a typical ferroelectric hysteresis loop of material. Peculiarity parameters can be prescribed, such as spontaneous polarization  $(P_s)$ , remnant polarization  $(P_r)$  and coercive field  $(E_c)$ . The grains in polycrystalline materials are often divided into several domains, owing to the necessity of the energy minima. At first, the domain directions are distributed randomly in such a way that they cause zero net macroscopic polarization (O point). Next, when the external field is greater than the  $E_{\rm C}$ , the polycrystalline ferroelectric material may be brought into a polar state (A point). Then, a macroscopic polarization is slowly induced by rising the electric field strength, as seen in Figure 4. Next, the harsh change in the polarization in the neighborhood of  $E_{\rm C}$  can be described by the polarization reversal (domain switching) (B point), while at high field end, the polarization is saturated and the material functions as a linear dielectric (C point). After that, some domains will backswitch as the electric field strength begins to reduce, but at zero field the net polarization is nonzero, come up with the remaining polarization  $P_r$  (D point). To achieve zero polarization, an electric field of the opposite direction is necessary in the last stage. This field strength is called the coercive field (or coercivity) (F point). The rising of this opposite field strength, causing a similar rearrangement of the polarization is founded in the negative field part (G point). The spontaneous polarization of the ferroelectric materials P<sub>s</sub> may be evaluated by intercepting the polarization axis with the foresee linear section, as shown in Figure 4. Furthermore, the ferroelectrics ordinarily have ferroelastic domains (unless for LiNbO<sub>3</sub>, which only has 180° ferroelectric domains), spontaneous strain is also created with the external electric field concurrently (38). Thus, if the strain is inspected as well as the polarization, a strain-electric field curve, like "butterfly", can be seen.

For perfect ferroelectric system, the ferroelectric hysteresis loops should be symmetric features. The positive and negative  $P_r$  and  $E_c$  values are equal. Whereas, the shape of the ferroelectric hysteresis loops in fact may be possible many factors, such as thickness of the samples, material composition, thermal treatment, existence of the charged flaws, mechanical stresses, measurement conditions and others. Their effect on the material properties may be well expressed through the loops.



Figure 4 A normal hysteresis loop in ferroelectrics, including domain reversal (polarization rotation) and strain-electric field curve.

#### **Dielectric** properties

Dielectric material will not conduct electricity and are critical importance on applied as capacitor in electronic devices (e. g., sensors, actuators, ultrasound transducers, etc.) and as insulators. The ceramic materials had very high charge-storing capabilities, i.e., relative dielectric constants k' > 1000.

In contrast to electrical conductivity, which relate to long-rang motion of charge carriers, the dielectric response comes from the short-rang motion of these carriers under the effect of an externally applied electric field. Because all solids consist of positive and negative identity, the application of an electric field to any solid will lead to a separation of its charges. This charge separation is called polarization.

Dielectric properties can vary widely among solids and are a function of temperature, frequency of applied field, moisture, crystal structure, and other external factors. Additionally, the response can be either linear or nonlinear. This section examines linear dielectrics including the influence of temperature and frequency on the dielectric response.

#### **Basic Theory**

Prior to discuss the ferro dielectric polarization, it is important to understand how one measures polarization and to obtained a qualitative understanding of how occur polarization is difficult or easy. Consider two metal parallel plates of area Aseparated by a distance d in vacuum, (Figure 5 (a)). These plates are connected to the basic electric circuit, seen in Figure 5 (a), and closing the circuit lead to arise a transient surge of current, which swiftly decays to zero, as represented in Figure 5 (b). Given that the area under the I against t curve is the total charge the flow through the circuit and now were stored on the capacitor plates, following the formula (1):

$$Q = \int I dt \tag{1}$$

Repeating the experiment at different voltages V and plotting Q against V should give a straight line, as seen in Figure 6. The slope of the Q against V curve is the capacitance  $C_{\text{vac}}$  of the parallel plates in vacuum, which was described below by following formula (2):

$$Q = CV$$
(2)

$$C_{vac} = \frac{\varepsilon_0 A}{d} \tag{3}$$

Where  $\varepsilon_0$  is the permittivity of free space, which is a constant (8.85x10<sup>-2</sup>  $C^2/J.m$ ). The units of capacitance are farads (*F*), where 1 *F*=1 *C*/*V*=1  $C^2/J$ .



Figure 5 (a) Parallel-plate capacitor of area A and separation d in vacuum connect with DC power source. (b) Closing of the circuit results in a transient surge of current to flow through the circuit. Charge collected on the capacitor is equal to the area under the curve. (c) Same as (a) except, now a dielectric is placed between the plates. (d) Closing of the circuit caused a charge retained on the parallel plates, which has to be greater than that stored in (b).

If a dielectric (which can be a gas, solid, or liquid) is introduced between the plates of the capacitor (Figure 5 (c)) and the aforementioned experiment is repeated, the current that flows through the external circuit and is stored on the capacitor plates will rise (Figure 5 (d)). Repeating the experiment at different voltages and plotting the total charge stored on the capacitor versus the voltage applied will again result in a straight line but with a larger slope than that for vacuum (Figure 5). In other words, equation (3) is now modified to read

$$C = \frac{\varepsilon A}{d} \tag{4}$$

Where  $\varepsilon$  is the dielectric constant of the material between the plates. The relative dielectric constant of a material k' is defined as

$$k' = \frac{\varepsilon}{\varepsilon_0} \tag{5}$$

Since  $\varepsilon$  is always greater than  $\varepsilon_0$ , the minimum value for k' is 1. By combining equation (4) and (5), the capacitance of the metal plates separated by the dielectric is

$$C = \frac{k'\varepsilon_0 A}{d} = k'C_{vac}$$
(6)

Thus k' is a dimensionless parameter that compares the charge-storing capacity of a material to that of vacuum.

The foregoing discussion can be summarized as follows: when a voltage is applied to a parallel-plate capacitor in vacuum, the capacitor will retain charge. In the presence of a dielectric, an additional "something" happens within that dielectric which allows the capacitor to retain more charge (35).



Figure 6 Functional dependence of Q on applied voltage. Slope of curve is associated to the dielectric constant of the materials.

#### Sintering

Sintering is the procedure by which a powder compact is changed to an athletic, dense ceramic body upon heating. In an alternate explanation given by Herring sintering is to mean any changes in shape which a tiny particle or a cluster of particles of uniform composition undergoes when maintained at high temperature. It can also be said that the sintering mean elimination of pores between particles along with shrinkage (densification) and grain growth (35, 39).

The decline of surplus energy associated with surfaces is the macroscopic driving factor at work during sintering. This can occur by (1) decline of the overall surface area owing to a rise in particles average size, resulting in coarsening (Figure 7 (b)), and/or (2) the removal of solid/vapor interfaces and the formation of grain boundary area, followed by grain growth, resulting in densification (Figure 7 (a)). These two processes are commonly in jousting. If the atomic mechanisms that cause densification dominate, the pores get decrease and eventually vanish and the compact shrinks. However, if the atomic mechanisms that lead to coarsening are quicker, the pores and grains will grow with time.



Figure 7 Schematic of two possible paths by which a collection of particles can lower its energy. (a) Densification followed by grain growth. In this case shrinkage of the compact has to happen (b) Coarsening where the large grains grow at the expense of the smaller ones.



## Figure 8 (a) Equilibrium dihedral angle between grain boundary and solid/vapor interfaces, (b) Equilibrium dihedral angle between grain boundary and liquid phase.

An essential condition for densification to arise is that the grain boundary energy  $\gamma_{gb}$  be less than twice the solid/vapor surface energy  $\gamma_{sv}$ . This indicates that the equilibrium dihedral angle  $\phi$  seen in Figure 8 (a) and defined as has to be less than 180°. For numerous oxide systems, the dihedral angle is ~120°, suggesting that  $\gamma_{gb} / \gamma_{sv} \approx 1.0$ , as opposed to metallic systems where that ratio is near to between 0.25 and 0.5 (35, 40).

$$\gamma_{gb} = 2\gamma_{sv}\cos\frac{\phi}{2} \tag{7}$$

#### **Sintering stages**

Coble explained a sintering phase as an "interval of geometric change in which pore shape is totally assign (such as rounding of necks during the initial phase sintering) or an interval of time during which the pore remains constant in shape while declining in size." Based on that definition, three phases have been classified: an initial, an intermediate, and a final phase. During the initial phase, the interparticle contact area rises from 0 to ~0.2 by neck development (Figure 9 (b)), and the relative density rises from about 60 to 65%. The intermediate phase is unique by continuous pore channels that are coincident with three-grain edges (Figure 9 (c)). During this

stage, the relative density increases from 65 to about 90% by having matter diffuse toward, and vacancies aloof from the long cylindrical channels. The final phase begins when the pore phase is ultimately squeezed off and is unique by the absence of a continuous pore channel (Figure 9 (d)). Individual pores are either of lenticular shape, if they reside on the grain boundaries, or rounded, if they reside within a grain. A significant feature of this phase is the rise in mobilities of pore and grain boundary, which must be regulated if the theoretical density is to be acquire (41).



Figure 9 (a) The spheres in tangential contact indicate the initial phase of the sintering model, (b) The spheres have begun to form as the initial phase draws to a close, (c) Intermediate phase; grains adopted shape of dodecahedra, enclosing pore channels at grain boundary, (d) Pores are tetrahedral inclusions in the corners where four dodecahedra converge in the final phase.

#### A literature reviews

The advancement of piezoelectric materials has resulted in a broad range of applications from regular use to more specialized devices such as sensors, actuators, ultrasound transducers, medical devices, etc (42-45). The perovskite ferroelectric materials are widely recognized for their remarkable piezoelectricity. In 1954, Jaffe B et al. discovered lead-based Pb(Zr,Ti)O<sub>3</sub> (PZT) piezoelectric ceramics and have been extensively used owing to their large piezoelectric coefficient ( $d_{33}$ ~200-750 pC/N) and high Curie temperature ( $T_{C}$ ~180-320°C) (1-4, 45). Unfortunately, lead-based materials are banned by global laws and regulations because of their high toxicity causing a great threat to environmental and human health. Hence, scientists have concentrated their tremendous efforts on the development of lead-free replacements. Potassium Sodium Niobate; [(K, Na) NbO<sub>3</sub>)] (KNN) ceramics

Since entering the 21<sup>st</sup> century, the lead-free KNaNbO<sub>3</sub> perovskite ceramics has become one of the most widely inspected piezoelectric systems because of its large  $d_{33}$  and high  $T_c$ . KNN solid solution is formed by potassium niobate (KNbO<sub>3</sub>) ferroelectric compound having space group a Cm2m and sodium niobate (NaNbO<sub>3</sub>) antiferroelectric compound having space group a *Pbma* with an orthorhombic perovskite phase at room temperature (46-48). Figure 10 displays the single orthorhombic structure at room temperature of KNN ceramics. The composition around x=0.5 is of great attention owing to the superior ferroelectric and piezoelectric behaviors. The K<sub>0.5</sub>Na<sub>0.5</sub>NbO<sub>3</sub> (KNN) ceramic undergoes three phase transitions, from rhombohedral to orthorhombic  $(T_{R-O})$  around -110°C, orthorhombic to tetragonal  $(T_{\text{O-T}})$  around 180°C, and tetragonal to cubic  $(T_{\text{T-C}})$  around 400°C, as seen in Figure 11. However, the main drawbacks of this ceramic can be attributed to two main factors. First, according to the phase diagram of KNbO<sub>3</sub>-NaNbO<sub>3</sub> (Figure 12), the KNN ceramic is decomposed beyond 1140°C (49). Thus, the high sintering temperature is not appreciated. Second is evaporation of alkali elements (K and Na) at high temperature which makes it is difficult to maintain the proper chemical stoichiometry and obtain high dense of ceramics (50-52).



Figure 10 Orthorhombic perovskite structure of KNN ceramic at room

temperature.

![](_page_32_Figure_0.jpeg)

Figure 12 The binary phase diagram of KNbO<sub>3</sub>-NaNbO<sub>3</sub>.

(K<sub>0.5</sub>Na<sub>0.5</sub>)(Nb<sub>1-x</sub>Ta<sub>x</sub>)O<sub>3</sub> (KNNT) ceramics

In 2009, Y.G. Lv et al. (10) prepared  $(K_{0.5}Na_{0.5})(Nb_{1-x}Ta_x)O_3$  (KNNT) ceramics with x=0, 0.10, 0.15, 0.20, 0.25 and 0.30 mol.% using the solid-state reaction method (calcination temperature of 900°C for 5 h and a sintering temperature of 1090-1180°C for 2 h). The XRD data of the all ceramics showed pure perovskite structure with single orthorhombic phase, as is demonstrated in Figure 13. This implies that Ta is completely diffuse into B-site in the KNNT lattice. SEM image of the KNNT ceramics with different x are indicated in Figure 14 (a-f). The grains of all the ceramics showed quadrate shape. The average grain size of KNN ceramic was about > 5  $\mu$ m, and all the KNNT ceramics have smaller grain sizes than the pure KNN system. The typically temperature dependence of dielectric constant of the KNNT ceramics (x=0, 0.15 and 0.30 mol.%) at the measuring frequency of 100 kHz over wide temperatures range between 0 and 500°C are shown in Figure 15. All samples showed three phase transition peaks, associate with the rhombohedral ferroelectricorthorhombic ferroelectric phase transition  $(T_{R-O})$ , the orthorhombic ferroelectrictetragonal ferroelectric phase transition  $(T_{O-T})$  and tetragonal ferroelectric-cubic paraelectric phase transition ( $T_{\rm C}$ ), respectively (53). They found that the  $T_{\rm R-O}$ gradually shifted to higher temperatures (see inset Figure 15), while the both  $T_{O-T}$  and  $T_{\rm C}$  gradually shifted to lower temperatures with the rising x. The dielectric constant  $(\varepsilon_{\rm C})$  tends to decreased when the rising x. Table 1 summarize the data of measured density, relative density, dielectric properties and piezoelectric coefficients at room temperature of KNNT ceramics with different x. With x=0.30 mol.%, the sample exhibited highest the density ( $\rho \sim 4.92 \text{ g/cm}^3$ ) and  $d_{33}$  ( $\sim 205 \text{ pC/N}$ ).

![](_page_34_Figure_0.jpeg)

Figure 13 XRD pattern at room temperature of the K<sub>0.5</sub>Na<sub>0.5</sub>Nb<sub>1-x</sub>Ta<sub>x</sub>O<sub>3</sub> ceramics with x=0-0.30 mol.%.

![](_page_35_Figure_0.jpeg)

Figure 14 SEM images of K<sub>0.5</sub>Na<sub>0.5</sub>Nb<sub>1-x</sub>Ta<sub>x</sub>O<sub>3</sub> ceramics with different x; (a) 0.00 mol.%, at 1090°C (b) 0.10 mol.%, at 1110°C, (c) 0.15 mol.%, at 1120°C, (d) 0.20 mol.%, at 1145°C, (e) 0.25 mol.%, at 1150°C and (f) 0.30 mol.%, at 1170°C.


Figure 15 The dielectric constant against temperature of the K<sub>0.5</sub>Na<sub>0.5</sub>Nb<sub>1-x</sub>Ta<sub>x</sub>O<sub>3</sub> ceramics with various x, measured at 100 *k*Hz.

Table 1 The density values, dielectric properties and piezoelectric coefficient at room temperature of the K<sub>0.5</sub>Na<sub>0.5</sub>Nb<sub>1-x</sub>Ta<sub>x</sub>O<sub>3</sub> ceramics with different x.

KNNT	x=0.00	x=0.10	x=0.15	x=0.20	x=0.25	x=0.30
$\rho$ (g/cm <sup>3</sup> )	4.27	4.44	4.63	4.73	4.86	4.92
$\rho$ (%)	94.21	93.08	95.27	94.04	94.37	94.40
$\varepsilon$ at 1 <i>k</i> Hz	470	507	656	683	889	967
$\tan \delta$ (%)	1.21	1.93	1.92	2.32	2.71	2.53
<i>d</i> <sub>33</sub> ( <i>p</i> C/N)	124	133	151	159	177	205
<i>d</i> <sub>31</sub> ( <i>p</i> C/N)	56	57	65	60	72	81

F. Jean et al. (54) synthesized  $(K_{0.5}Na_{0.5})(Nb_{1-x}Ta_x)O_3$  ceramics with x=0, 0.05, 0.10, 0.20, 0.30, 0.50 and 1.0 mol.% using the spark plasma sintering method (two calcination temperature of 830°C for 5 h and a sintering temperature of 920-

980°C for 5-10 min). The evolution of  $d_{33}$  of the K<sub>0.5</sub>Na<sub>0.5</sub>Nb<sub>1-x</sub>Ta<sub>x</sub>O<sub>3</sub> ceramics with various x are shown in Figure 16. The  $d_{33}$  value tended to increase from ~120 to 160 *p*C/N upon x increased from 0 to 0.3 mol.% and then dropped.



Figure 16 The evolution of  $d_{33}$  in K<sub>0.5</sub>Na<sub>0.5</sub>Nb<sub>1-x</sub>Ta<sub>x</sub>O<sub>3</sub> ceramics with different x.

Honghui Gu et al. (55) fabricated KNNT ceramics using the hydrothermal method (sintering temperature of 1160-1200°C for 2 h). Figure 17 depicts the polarization hysteresis (*P-E*) loops of the KNNT ceramics with different sintering temperature. All compositions exhibited typical and slim *P-E* loops. The samples showed remnant polarization (*P*<sub>r</sub>) values of 22.91, 19.33, 19.01, 13.64 and 13.00  $\mu$ C/cm<sup>2</sup> as well as *E*<sub>C</sub> values of 3.7, 4.3, 3.3, 3.4 and 3.5 *k*V/cm, respectively.



Figure 17 Polarization hysteresis loops of the KNNT ceramics at different sintering temperature.

The improvement in density and electrical properties by additional and/or substitutional doping with elements or compounds in A-site of KNNbased ceramics

1. For the substitutional doping of element or compounds in KNN-based ceramics

Changbai Long et al. (16) prepared (Na<sub>0.5</sub>K<sub>0.5</sub>)<sub>1-x</sub>Li<sub>x</sub>NbO<sub>3</sub> (KNN-xLi) ceramics with x=0, 0.055, 0.06, 0.065 and 0.07 mol.% using the conventional solid-state reaction method (calcination temperature of 800°C for 4 h and a sintering temperature of 1060 and 1100°C for 4 h). The XRD patterns of the KNN-xLi samples with different x are indicated in Figure 18 (a). All samples exhibited a pure perovskite phase and no trace of any secondary phase was identified. For further scrutiny of the phase composition of all samples, enlarged XRD patterns at  $2\theta$  around ~31-47° is plotted in Figure 18 (b). According to Figure 18 (b), the intensity of the (220) peak in KNN is much higher than of the (002) one, with  $I_{(022)}/I_{(200)}$  value of being around 2, confirming its orthorhombic phase. Moreover, the diffraction peaks of KNN-xLi ceramics shift towards high diffraction angles with the rising x, which pointed out to shrunk unit cells because of the doping with Li<sup>+</sup> of smaller size [1.15 Å, 12 CN (coordination number)] as compared with those of K<sup>+</sup> (1.64, 12 CN) and Na<sup>+</sup> (1.39 Å, 12 CN) (56, 57). Upon rising x, the (022) peak is suppressed, whereas the relative intensity of the (200) one is increased. In the x=0.06 sample, a typical MPB composition can be seen (48, 58). However, further Li<sup>+</sup> substitutional doping inhibited the orthorhombic structure. Tetragonal structure is prominent in the x=0.07 sample.

In validate and perfect the XRD studies, Rietveld refinement was done on the samples at x=0.06 and 0.07 using the Fullprof software (59, 60). The orthorhombic (space group *Amm2*) and tetragonal (space group *P4mm*) phases of KNbO<sub>3</sub> were selected as the starting models (61). Investigation from Figure 19 (a-b), for each sample, the refined profile well fits to the experimental data. Table 2. lists the reliability factors, lattice parameters and phase percentage of these two compositions. It was found that the calculated quality of the fits was  $R_p \le 0.0384\%$ ,  $R_{wp} \le 0.0522\%$  and  $\chi^2 \le 1.476$  (Table 2). With x=0.06, the sample had a typical two-phase co-existence composition, where the proportions of orthorhombic phase and tetragonal phase are 58.37% and 41.63%. Upon increasing x, the proportions of orhorhombic:tertragonal phase increased.



Figure 18 XRD patterns at room temperature of the KNN-xLi ceramics in the  $2\theta$  (a) 20-60° and (b) 31-47°, and the  $I_{(022)}/I_{(200)}$  ratios of all samples as an inset in

(a).

Figure 20 (a-e) shows the microstructure of the KNN-xLi samples with different x. The grain of ceramic exhibited square or rectangular shape. When compared to the pure KNN ceramic, there is no significant difference in grain size for the x=0.055 and x=0.06 samples. For x>0.06, the grains of the ceramics grow swiftly, and the average grain sizes of the KNN-0.065Li and KNN-0.07Li samples are nearly twice of KNN. This result can be explained by the appearance of liquid-phase sintering, which facilitated the grain growth. Furthermore, the energy barrier for the jump of the oxygen vacancies in the distorted structure may be higher than in the non-distorted structure (62). So, the transport of oxygen ions in the tetragonal phase may be easier than in the orthorhombic phase. Hence, the oxygen diffusion in the grains and/or grain boundaries was increased in the KNN-0.065Li and KNN-0.07Li ceramics with dominant tetragonal phase.

Figure 21 depicts the temperature dependence of dielectric constant ( $\varepsilon$ ) and dielectric loss (tan  $\delta$ ) of the KNN-xLi samples, which are measured at frequency of 10 *k*Hz over wide temperatures range between 0 and 500°C. All ceramics showed two

phase transition peaks, associate with the orthorhombic ferroelectric-tetragonal ferroelectric phase transition  $(T_{O-T})$  and tetragonal ferroelectric-cubic paraelectric phase transition ( $T_C$ ), respectively (Figure 21 (a)) (63). The  $T_{O-T}$  of the ceramics shifted to low temperature from 197 to 60°C with increasing x from 0 to 0.07. On the contrary, the  $T_{\rm C}$  of ceramics moved to high temperature from 428 to 470°C with rising x from 0 to 0.07. In the inset of Figure. 21 (a), the changes in  $T_{\text{O-T}}$  and  $T_{\text{C}}$  of all compositions can be apparently seen. The increased tetragonal distortion of the ceramics results in  $T_{\rm C}$  rising. The Li<sup>+</sup> substitution can be improved the dielectric constant at Curie temperature ( $\varepsilon_{\rm C}$ ) of the ceramics (Figure 21 (a)). Furthermore, the loss peak at  $T_{\rm C}$  shifted to high temperature upon rising x and the heights of these peaks of the Li substitution were enhanced heavily (Figure 21 (b)). The high loss generated by the Li<sup>+</sup> doping may be ascribed to high concentration flaws due to the appearance of the liquid phase and the over-growth grains. Figure 22 demonstrates the remanent polarization ( $P_r$ ), field-induced strain ( $S_{33}$ ) and  $d_{33}$  of the KNN-xLi ceramics with different x. The  $P_r$ ,  $S_{33}$  and  $d_{33}$  tends to enhanced when x increased up to 0.06, and then dropped. With x=0.06, the sample show highest  $P_r$ ,  $S_{33}$  and  $d_{33}$  of ~25  $\mu$ C/cm<sup>2</sup>, ~0.13% and ~190 pC/N, respectively. This phenomenon can be explained by the MPB region, resulting in increment of the electrical properties.





Figure 19 Rietveld refinements on XRD data for (a) the KNN-0.06Li and (b) the KNN-0.07Li ceramics.

Table 2 Crystal data and structure refinement conditions for the KNN-0.06Liand KNN-0.07Li. The distortions for orthorhombic phase andtetragonal phase are designed as 2(c-b)/(c+b).

KNN-0.06Li		KNN-0.07Li		
Orthorhombic	Tetragonal	Orthorhombic	Tetragonal	
Amm2	P4mm	Amm2	P4mm	
58.37	41.63	24.43	75.57	
3.94306	3.95542	3.93538	3.93538	
5.62203	3.95542	5.62135	5.62135	
5.67042	4.00699	5.66264	5.66264	
125.702	62.691	125.270	125.270	
0.857	1.295	0.732	0.732	
0.0522	-	0.0529	-	
0.0389		0.0384	-	
1.476		1.588	-	
1.21	120	1.26	-	
	KNN-0 Orthorhombic Amm2 58.37 3.94306 5.62203 5.67042 125.702 0.857 0.0522 0.0389 1.476 1.21	KNN-0.06LiOrthorhombicTetragonalAmm2P4mm58.3741.633.943063.955425.622033.955425.670424.00699125.70262.6910.8571.2950.0522-0.0389-1.476-1.21-	KNN-0.06LiKNN-0OrthorhombicTetragonalOrthorhombicAmm2P4mmAmm258.3741.6324.433.943063.955423.935385.622033.955425.621355.670424.006995.66264125.70262.691125.2700.8571.2950.7320.0522-0.05290.0389-0.03841.476-1.5881.21-1.26	



Figure 20 SEM micrographs of KNN-xLi ceramics with different x (a) 0, (b) 0.055, (c) 0.06, (d) 0.065 and (e) 0.07. The insets depict grain size distributions.



Figure 21 Temperature dependence of (a) dielectric permittivity and (b) dielectric loss of the KNN-xLi samples with different x.



Figure 22 The *P*<sub>r</sub>, *S*<sub>33</sub> and *d*<sub>33</sub> for the KNN-xLi samples with different x.

2. For the additional doping of element or compounds in KNN-based ceramics

Xiaodan Ren et al. (64) investigated the effect of Li<sub>2</sub>O on the structure and electrical properties of  $0.93K_{0.5}Na_{0.5}NbO_3$ - $0.07SrZrO_3$ - $xLi_2O$ ; 0.93KNN-0.07SZ-xLi ceramics (x=0, 0.03, 0.07, 0.10, and 0.13 wt.%) using the conventional solid-state method (calcination temperature of 850°C for 5 h and a sintering temperature of 1270 and 1280°C for 6-10 h). The XRD patterns at room temperature of 0.93KNN-0.07SZ-xLi ceramics with various x are exhibited in Figure 23. With  $0 \le x \le 0.07$ , the samples display pure perovskite structure (Figure 23 (a)). When  $x \ge 0.07$ , the impurity phase of  $K_3Li_2Nb_5O_{15}$  is identified (Figure 23 (a)). For further scrutiny of the phase formation, the diffraction peaks at the  $2\theta$  range from 44-48° was amplified (Figure 23 (b)). The ceramics with x=0 present orthorhombic phase. After that, the tetragonal phase gradually emerges as x rises from 0.03, 0.07 to 0.10 and ultimately entirely becomes a tetragonal phase with x=0.13.



Figure 23 XRD patterns of 0.93KNN-0.07SZ-xLi ceramics in the  $2\theta$  range of (a) 10-70° and (b) 44-48°.

Figure 24 (a-e) shows the SEM images of 0.93KNN-0.07SZ-xLi ceramics. With x=0, the morphology of ceramic exhibited small grains and good mass density (Figure 24 (a) and (f)). As x rising, the grains grow significantly and an inhomogeneous grain distribution appears (Figure 24 (a) and (f)). When x=0.03, the

sample shows small grains intercalate between large grains, leading to higher bulk density (Figure 24 (f)).



Figure 24 SEM image of 0.93KNN-0.07SZ-xLi ceramics with (a) x=0, (b) x=0.03, (c) x=0.07, (d) x=0.10, (e) x=0.13 and (f) The average grain size and bulk density of the 0.93KNN-0.07SZ-xLi ceramics with different x.

The temperature dependence of the dielectric constant ( $\varepsilon$ ) and loss tangent (tan  $\delta$ ) of the 0.93KNN-0.07SZ-xLi ceramics at varying frequencies (1-200 *k*Hz) are shown in Figure 25. All ceramics showed two phase transition peaks, associate with the orthorhombic ferroelectric-tetragonal ferroelectric phase transition at ~ 130°C ( $T_{\text{O}-T}$ ) and tetragonal ferroelectric-cubic paraelectric phase transition at ~ 280°C ( $T_{\text{m}}$ ), respectively (Figure 25 (a-e)) (64). The  $T_{\text{m}}$  of ceramics tend to enhanced when rising x (Figure 25 (a-e)). The  $\varepsilon_{\text{r}}$  of samples enhanced when x increases from 0 to 0.03, and then dropped (Figure 25 (a-e)). The samples with x=0.03 show highest the  $\varepsilon$  as 9643. Figure 25 (f) presents the plot of  $T_{\text{m}}$  and  $\varepsilon$  of 0.93KNN-0.07SZ-xLi ceramics with different x.



Figure 25 Temperature-dependent dielectric constant and dielectric loss of the 0.93KNN-0.07SZ-xLi ceramics with (a) x=0, (b) x=0.03, (c) x=0.07, (d) x=0.10, (e) x=0.13 and (f) The  $T_{\rm m}$  and  $\varepsilon$  of the 0.93KNN-0.07SZ-xLi ceramics with different

x.

Figure 26 (a) displays the polarization-electric field (P-E) hysteresis loops of the 0.93KNN-0.07SZ-xLi ceramics with different x. The saturated P-E loops appear in all samples, but the saturation characteristic goes gradually reduced when x rises, indicating a strengthened relaxor behavior. Figure 26 (b) demonstrates the remanent polarization ( $P_r$ ),  $d_{33}$  and  $K_p$  of the 0.93KNN-0.07SZ-xLi ceramics with different x. The  $P_r$ ,  $d_{33}$  and  $k_p$  tends to enhanced when x increased up to 0.03, and then dropped. The sample with x=0.03 shows highest  $P_r$ ,  $d_{33}$  and  $k_p$  of ~15  $\mu$ C/cm<sup>2</sup>, ~150 pC/N and  $\sim 0.26\%$ , respectively. To feature the thermal stability of the ceramics, the correlation between normalized  $d_{33}$  ( $d_{33}(T)/d_{33}(RT)$ ) and annealing temperature (Ta) was inspected, as shown in Figure 26 (c). They reported that  $d_{33}$  decrease slightly with Ta increased and then drops swiftly when Ta exceeds  $T_c$ . In particular, the piezoelectricity retains 86% ( $d_{33}$ ~129 pC/N) of the room temperature value as Ta goes up to 270°C. Figure 26 (d) displays schematic diagram of the reason for d<sub>33</sub> increasing at x=0.03. It can be seen that introduction of  $Li^+$  cause abnormal grain growth (AGG), while some grains retain their size and occupy the interstitial positions of the large grains, leading to a highest bulk density and  $d_{33}$  of the samples.



Figure 26 (a) *P*-*E* loops and (b) the variation of  $P_r$ ,  $d_{33}$  and  $k_p$ ; (c)  $d_{33}$  against annealing temperature of the 0.93KNN-0.07SZ-xLi samples with various x; (d) Schematic diagram explains why the sample with x = 0.03 has a high  $d_{33}$ .



### **CHAPTER III**

# **RESEARCH METHODOLOGY**

This chapter elaborates the experimental procedure, which contains the samples synthesis and characterization. The  $(K_{0.5}Na_{0.5})(Nb_{0.7}Ta_{0.3})O_3$  with different firing conditions, and  $K_{0.5-x}Cs_xNNT$ , KNNT-xCs,  $KN_{0.5-x}Li_xNT$  and KNNT-xLi with different x are synthesized using solid-state combustion technique. The details of the experimental procedure are set out in the following sections.

#### **Samples Synthesis**

The solid-state combustion method has been broadly used in preparation electro ceramics owing to its reduced firing temperature and soaking time and the production of a pure phase with ultrafine homogeneous particles. The main benefit of this approach results from the release from the ignition of fuel (i.e., glycine), which speeds up the chemical reaction between raw materials and also helps to reduce the reaction temperature. Including, ceramics fabricated by this technique display high density and good electrical behaviors.

# The synthesis of powders and ceramics of KNNT, K<sub>0.5-x</sub>C<sub>sx</sub>NNT, KNNTxCs, KN<sub>0.5-x</sub>Li<sub>x</sub>NT and KNNT-xLi at x=0, 0.10, 0.02, 0.03 and 0.04 mol.%

Analytical-grade metal oxides and carbonate powders of KHCO<sub>3</sub> (99.7%, Ajax, NZ), NaNO<sub>3</sub> (99%, Ajax, NZ), Nb<sub>2</sub>O<sub>5</sub> (99.99%, Eleps, RU), Ta<sub>2</sub>O<sub>5</sub> (99%, Sigma, CN), Cs<sub>2</sub>CO<sub>3</sub> (99.7%, Ajax, NZ) and Li<sub>2</sub>CO<sub>3</sub> (99%, Sigma, CN) were used as the starting materials for synthesizing samples. They were weighed and mixed in proportion the formulae: (8)  $[(K_{0.5}Na_{0.5})(Nb_{0.7}Ta_{0.3})O_3; KNNT],$  (9)  $[(K_{0.5-x}Cs_xNa_{0.5})(Nb_{0.7}Ta_{0.3})O_3; K_{0.5-x}Cs_xNNT (x=0, 0.01, 0.02, 0.03 and 0.04 mol.%)], (10) <math>[(K_{0.5}Na_{0.5})(Nb_{0.7}Ta_{0.3})O_3 - xCs_2CO_3; KNNT - xCs (x=0, 0.01, 0.02, 0.03 and 0.04 mol.%)], (11) <math>[(K_{0.5}Na_{0.5})(Nb_{0.7}Ta_{0.3})O_3 - xCs_2CO_3; KNNT - xLi_xNT (x=0, 0.01, 0.02, 0.03 and 0.04 mol.%)]$  and (12)  $[(K_{0.5}Na_{0.5})(Nb_{0.7}Ta_{0.3})O_3 - xLi_2CO_3; KNNT - xLi (x=0, 0.01, 0.02, 0.03 and 0.04 mol.%)]$ , (0.02, 0.03 and 0.04 mol.%)], where excess KHCO<sub>3</sub> and NaNO<sub>3</sub> were added 1 wt.% to compensate for the volatility of K and Na during calcination and sintering. The mixed

powders were ball-milled method within a poly bottle with zirconia balls in ethanol for 24 h. The suspensions were dried at a temperature of ~100°C and mixed with glycine in an agate mortar. The KNNT powders were calcined at a temperature between 600 and 800°C for 2 h in air. The K<sub>0.5-x</sub>Cs<sub>x</sub>NNT, KNNT-xCs, KN<sub>0.5-x</sub>Li<sub>x</sub>NT and KNNT-xLi powders were calcined at a temperature between 600°C for 2 h in air. Next, the calcined powders were combined with 3 wt.% polyvinyl alcohol (PVA) binder solution followed by ball-milled again for 12 h. The resultant mixtures were dried, sieved, and compacted into pieces at a pressure of 80 MPa with a diameter of  $\sim$ 15 mm and a thickness of  $\sim$ 1.5 mm using a hydraulic press. After burning off PVA, the KNNT samples were sintered at a temperature between 1150-1190°C for 2-5 h in air. For the K<sub>0.5-x</sub>Cs<sub>x</sub>NNT samples were sintered at 1130°C for 4 h in air. In the event of the KNNT-xCs, KN<sub>0.5-x</sub>Li<sub>x</sub>NT and KNNT-xLi samples were sintered at 1150°C for 4 h in air. For the SEM specimen preparation, the polishing with sandpaper and an alumina abrasive on the surface's samples were carried out. Then, they were thermally etched at a temperature 80°C less than the sintering temperature for 30 min to disclose their grain boundaries. To prepare the samples for their electric property measurements, the ceramics were coated with silver paste on both sides, to form electrodes, and then fired at 550°C for 30 min. The diagram of the synthesis process of KNNT, K<sub>0.5-x</sub>Cs<sub>x</sub>NNT, KNNT-xCs, KN<sub>0.5-x</sub>Li<sub>x</sub>NT and KNNT-xLi powders and ceramics are shown in the Figure 27, 28, 29, 30 and 31, respectively.





Figure 27 Diagram of the synthesis process of KNNT powders and ceramics.



Figure 28 Diagram of the synthesis process of K<sub>0.5-x</sub>Cs<sub>x</sub>NNT powders and

ceramics.





Figure 30 Diagram of the synthesis process of KN<sub>0.5-x</sub>Li<sub>x</sub>NT powders and ceramics.



Figure 31 Diagram of the synthesis process of KNNT-xLi ceramics.

## Samples Characterization

The KNNT powders were characterized about phase structure and microstructure with different tools, as seen in Figure 32.



Figure 32 Diagram of samples characterization of KNNT powders.

The  $K_{0.5-x}Cs_xNNT$ , KNNT-xCs,  $KN_{0.5-x}Li_xNT$  and KNNT-xLi ceramics were characterized about physical and electrical properties with different tools, as seen in Figure 33.



Figure 33 Diagram of samples characterization of K<sub>0.5-x</sub>Cs<sub>x</sub>NNT, KNNT-xCs,

KN<sub>0.5-x</sub>Li<sub>x</sub>NT and KNNT-xLi ceramics.

Physical properties

X-ray diffraction (XRD) technique (65)

X-ray diffraction analysis (XRD) is a technique used in materials science to evaluates the phase formation and phase purity of materials as well as complete information about crystallographic symmetry. In this study, the X-ray diffraction pattern of the samples was recorded using an X-ray diffractometer (XRD, Bruker, D2 Phaser) with Cu-K $\alpha$  radiation ( $\lambda = 1.5418$  Å) at room temperature. Figure 34 displays an X-ray diffractometer. For the detection limit, the XRD technique can't identify the deformation of a material substance with less than 5% of deformation in systems. The percentage purity of the perovskite structure can be calculated following the equation (13)

% perovskite phase = 
$$\left(\frac{I_{perovskite}}{I_{perovskite} + I_{impurity}}\right) \times 100$$
 (13)

Where  $I_{perovskite}$  is the highest intensity of the perovskite peak.

 $I_{impurity}$  is the highest intensity of impurity peak.



Figure 34 X-ray diffraction instruments

Rietveld refinement technique (66, 67)

Rietveld refinement technique was used to confirm the phase structure of samples by fitting the XRD information with the Fullprof software. Figure 35 demonstrated windows of the FullProf Suite toolbar. The original values of the cell parameters, lattice constants, space group and atom functional positions were acquired from the relating reference designs determined from the Crystallography Open Database (COD). A structural model based on KaNaNbO<sub>3</sub> with a tetragonal phase (T),

with a *P4mm* space group, and an orthorhombic phase (*O*), with an *Amm*2 space group, were used as the initiating models for refining the all ceramics' XRD data. A Chebyshev polynomial function was used to fit the background, and a Pseudo-Voigt function was used to characterize the peak shape. A linear combination of Lorentzian and Gaussian functions is known as the Pseudo-Voigt function. A principle of this program is minimizing the difference between calculated intensities (model data) and the observed intensity points (experimental data). The quality values such as  $R_p$  (profile reliability),  $R_{wp}$  (weighted pattern reliability),  $R_{exp}$  (expected residual) and  $\chi^2$  (goodness of fit) was used for the calculation to create the model data which was described below by following equations:

$$R_{p} = 100 \frac{\sum |y_{oi} - y_{ci}|}{\sum y_{oi}}$$
(14)

$$_{p} = 100 \left\{ \frac{\sum wi (y_{oi} - y_{ci})^{2}}{\sum wi (y_{oi})^{2}} \right\}^{1/2}$$
(15)

$$R_{\rm exp} = 100 \left\{ \frac{(N - P + C)}{\sum wi(y_{oi})^2} \right\}^{1/2}$$
(16)

$$\chi^{2} = \left[\frac{R_{wp}}{R_{exp}}\right]$$
(17)

Where:  $w_i$  is assigned a statistical weight.

 $y_{oi}$  is observed intensities for diffraction angle  $2\theta_i$ .

 $y_{ci}$  is calculated intensities for diffraction angle  $2\theta_i$ .

*N* is the total number of data point.

*P* is the number of parameters adjusted.

*C* is the number of constraints applied.

According to basic principle, R < 15% and  $\chi^2 < 4$  which is considered acceptable (66-68).

In summary, this technique provides the lattice constants, atomic vibration, fractional occupancy and percentage phase of samples.



Figure 36 Rietveld refinement on XRD patterns of KNNT ceramic at 1150°C for

X-ray photoelectron spectroscopy (XPS)

X-ray photoelectron spectroscopy (XPS) is an instrument used to inspect the chemical state of surface elements and detect chemical contamination of samples (Figure 37). It can analyze a sample to a depth of 2 to 5 *n*m. XPS is generally performed by exciting a samples surface with monochromatic  $Al - K_{\alpha}$  radiation causing releasing of photoelectrons from the sample surface. The energy of the emitted photoelectrons was measured using an electron energy analyzer. From the binding energy and intensity of a photoelectron peak, the elemental identity, chemical state, and quantity of an identified element can be determined (69, 70).



Figure 37 The XPS analysis of surface for pure copper sample.



#### Figure 38 X-ray photoelectron spectroscopy (XPS).

(EDS) (EDS) (EDS) (EDS) (EDS) (EDS)

Scanning electron microscopy (SEM) is an instrument used to examine the morphology of powders and ceramics, such as size, agglomeration, shape and presence of porosity. Figure 39 demonstrated the basic principle of the SEM machine. The magnification of this camera was in the range of 25,000-100,000x (71). A linear interception technique was used to estimate the average grain size of ceramics. D=L/N is the equation for a linear intercepting technique, where D represents the average grain size, L represents random linear lines on SEM micrograph and N is the total number of grain boundary intersections.

In addition, chemical analysis of the materials was carried out with Energy Dispersive Spectroscopy (EDS). For the principle of this technique, the beam of electrons is focused on the specimens. Atoms contain ground state electrons inside the material, which these electrons reside in discontinuous energy levels from the nucleus. Anywise, the electron beam can eject an electron from an inner shell leaving a hole, which is subsequently filled by the falling of an electron from an outer shell or higher energy level, as seen in Figure 40. The energy difference between these two energy levels was released in the form of an X-ray. The amount and energy of this X- ray can be determined by a spectrometer. The released X-rays energies are the characteristics of the difference in the energy levels and atomic structure of each element which they were emitted. Therefore, the kind and quantity of the element in specimens can be specified (72). Figure 41 display Scanning Electron Microscope (SEM).



Figure 39 Schematic diagram of typical scanning electron microscope.



Figure 40 The interaction between an electron beam and electrons inside an



Figure 41 Scanning electron microscope (SEM).

Transmission electron microscopy (TEM) and Selected area electron diffraction (SAED)

Transmission electron microscopy (TEM) is highly powerful instrument in material science. A high-energy beam of electron is shone through a very thin specimen, and the interaction between the electrons and atoms can be used to investigated the surface structure i.e., defects, crystal structure of the atom, shape and size of the particle. The magnification of this camera was in the range of 25,000-700,000x (71, 73). Figure 42 illustrated the basic principle of the TEM machine. Selected area electron diffraction (SAED) pattern was used to study the phase structure and crystalline character of materials. Figure 43 display transmission electron microscopies (TEM).



Figure 42 Schematic diagram of typical transmission electron microscopy.



Figure 43 Transmission electron microscopy (TEM).

## Densification measurement

The density measurement of the ceramics was evaluated by Archimedes' technique (74) using distilled water as the medium. This concept can be explained that an object totally or partially immersed in a fluid is buoyed up by a force equal to the weight of the fluid that is displaced. It is determined by the following equation 18;

$$\rho_{mea} = \frac{W_1}{W_1 - W_2} \times \rho_w \tag{18}$$

Where  $\rho_{mea}$  denotes the measured density of the samples (g/cm<sup>3</sup>).

- $W_1$  denotes the dry weight of the samples (g).
- $W_2$  denotes the weight immersed in the water of the samples (g).
- $\rho_w$  denotes the density of water for immersion the samples (g/cm<sup>3</sup>).

#### **Electrical properties**

Dielectric measurement

The dielectric behaviors of the ceramics were evaluated at a frequency of 1, 10 and 100 *k*Hz over a temperature range of 30-400°C. Figure 44 display the computer-controlled dielectric measurement system consists of an LCR-meter (Agilent 4263B), a temperature chamber and a computer system. The dielectric constant can be described by the following equation 19: (75, 76)



(19)

where  $\varepsilon_r$  represents the dielectric constant.

- $\varepsilon_0$  represents the permittivity of free space.
- C represents the capacitance.
- *t* represents the thickness of the ceramics.
- A represents the area of the ceramics.



Figure 44 The LCR meter at Naresuan University.

Ferroelectric properties measurements

The ferroelectric hysteresis loops (*P*-*E*) of samples were carried out at room temperature and frequency of 1 Hz using a computer controlled modified Sawyer Tower circuit (Radiant, PLC2-1014346), which was measured under electrical field of 40-45 kV/cm. Figure 45 display the computer controlled modified Sawyer Tower circuit (77-79).



Figure 45 The computer controlled modified Sawyer Tower circuit.



# **CHAPTER IV**

# **RESULTS AND DISCUSSION**

**1.** Effect of firing conditions on phase formation, microstructure, and electrical properties of (K<sub>0.5</sub>Na<sub>0.5</sub>)(Nb<sub>0.7</sub>Ta<sub>0.3</sub>)O<sub>3</sub> ceramics synthesized by solid-state combustion method

Figure 46 presents the X-ray diffraction pattern revealing the phase content of the KNNT powders after calcination at temperatures in the range from 600°C to 800°C for 2 h. It was found that all the samples exhibited pure perovskite structure resembling Joint Committee on Powder Diffraction Standards (JCPDS) files no. 01-071-0946 (orthorhombic phase) and 01-071-0945 (tetragonal phase). For comparison, the pure perovskite phase was obtained from the samples calcined at 600°C for 2 h, which is 300°C less than that reported for the solid-state reaction technique, which used 900°C and 3 h (10). This reduction in temperature and time is a result of the liquid medium, when glycine melts, and the energy released from the combustion of glycine (80).



Figure 46 X-ray diffraction patterns of KNNT powders calcined at temperatures between 600 and 800°C for 2 h in the  $2\theta$  range of 10-70°.



Figure 47 SEM images of KNNT powders calcined at the temperatures of: (a) 600, (b) 650, (c) 700, (d) 750 and (e) 800°C for 2 h.

Figure 47 (a-e) shows SEM images of the KNNT powders calcined at different temperatures between 600 and 800°C for 2 h. It was observed that all the calcined KNNT powders exhibited fine particles and rather spherical morphology. The particle agglomerations in the powders increased when the calcination temperature was increased (Figure 47 (a-e)). The average particle size of the KNNT powders increased from 0.161±0.042 to 0.259±0.048  $\mu$ m when the calcination temperature was increased from 600 to 800°C. The morphology and crystallinity of the powder calcined at 600°C for 2 h were studied by TEM (Figure 48 (a-d)). Figure 48 (a) shows a TEM image at low magnification, where thickly agglomerated particles can be observed. At high magnification (Figure 48 (b)), rather square shapes were revealed, and particle sizes of ~ 160 *n*m could be measured. This value is close to the particle size measured by SEM. Figure 48 (c) shows the selected-area electron diffraction (SAED) pattern, revealing spotty ring patterns that indicate a polycrystalline character (81). The ring patterns observed by SAED demonstrate the coexistence of orthorhombic and tetragonal phases, in correspondence with the XRD results described above.




Figure 48 (a-c) TEM micrograph and (d) SAED pattern of KNNT powders calcined at temperature of 600°C for 2 h.





Figure 49 X-ray diffraction patterns of KNNT ceramics with various sintering temperatures in the 2θ range of (a) 10-70° and (b) 24-36°; filled club, Nb<sub>2</sub>O<sub>5</sub>; filled circle, KNO<sub>3</sub>; filled heart, KO<sub>2</sub>; filled diamond, NaNO<sub>2</sub>; filled spade,

KNaO.

The XRD patterns of the ceramics sintered at temperatures between 1150 and 1190°C for 2 h are shown in Figure 49 (a-b). A pure perovskite structure in the KNNT ceramics was obtained after sintering at 1150°C for 2 h. After sintering at temperatures >1150°C for 2 h, secondary phases such as Nb<sub>2</sub>O<sub>5</sub>, KNO<sub>3</sub>, and KO<sub>2</sub> were detected. After sintering at 1180 and 1190°C for 2 h, impurity peaks corresponding to NaNO<sub>2</sub> and KNaO also appeared. The quantity of perovskite structure. The percentage purity of the perovskite structure in the sintered KNNT ceramics was calculated using Eq. 20,

$$Perovskite = \left(\frac{I_{perov}}{I_{perov} + I_{Nb_2O_5} + I_{KNO_3} + I_{KO_2} + I_{NaNO_2} + I_{KNaO}}\right) \times 100$$
(20)

This equation can be used to compute the purity percentage of the perovskitestructured materials, (82, 83) where  $I_{perov}$  is the maximum intensity of the perovskite peak and  $I_{Nb_2O_5}$ ,  $I_{KNO_3}$ ,  $I_{KO_2}$ ,  $I_{NaNO_2}$ , and  $I_{KNaO}$  are the highest-intensity peaks of the impurities. The perovskite percentage of all the sintered KNNT ceramics is presented in Figure 49 (a). The presence of impurity phases after sintering at temperatures >1150°C can be explained by the volatilization of Na<sub>2</sub>O and K<sub>2</sub>O during the sintering process (84, 85). Moreover, previous research has reported that different dwell times affect the densification, microstructure, and electric properties of ceramics (86, 87). It may thus be essential to examine the effect of dwell time during sintering on the density value, microstructure, and electrical properties of the ceramics with a sintering temperature of 1150°C.

Figure 50 shows the room-temperature XRD patterns in the 2 h range of 10° to 70° for all the ceramics sintered at 1150°C with different dwell times. All the ceramics possessed pure perovskite structure, and no secondary impurity could be detected. The phase structure of all the ceramics corresponded to JCPDS files no. 01-071-0946 (orthorhombic phase) and 01-071-0945 (tetragonal phase), in accordance with previous reports (9).



Figure 50 X-ray diffraction patterns of KNNT ceramics at a sintering temperature of 1150°C for the different dwell times of 2-5 h in the  $2\theta$  range of

Table 3 Goodness of fit parameters, lattice parameters, atomic information and<br/>the percentage of phases for KNNT ceramics with different dwell times<br/>during sintering.

Dwell	Goodness of	Phase	Profile	Atoms information			The		
time	fit	structures	parameters	Label	x	у	z	Occ.	percentage of
( <b>h</b> )									phase
2	χ <sup>2</sup> =2.15	Amm2	a=3.954 Å	Na	0	0	0.0453	0.60479	
	$R_{\rm p} = 13.8\%$		$b{=}5.626\text{\AA}$	К	0	0	0.0453	0.50137	
	$R_{\rm w} = 14.8\%$		c=5.645 Å	Nb	0.5	0	0.5251	0.61646	68
	$R_{exp} = 10.07\%$		<i>u</i> =0.011	Та	0.5	0	0.5251	0.30270	
			v=0.024	01	0	0	0.4727	1.22985	
			w=0.009	02	0.5	0.7535	0.2285	1.03943	
		P4mm	a=3.990 Å	Na	0	0	0	0.45192	
			c=3.965 Å	К	0	0	0	0.49912	
			c/a=0.993	Nb	0.5	0.5	0.492	0.64531	
			<i>u</i> =0.508	Та	0.5	0.5	0.492	0.30086	32
			v=-0.168	01	0.5	0.5	0.038	1.21856	
			w=0.072	02	0.5	0	0.5 <mark>39</mark>	2.30 <mark>5</mark> 11	
3	χ <sup>2</sup> =2.05	Amm2	a=3.956 Å	Na	0	0	0.0453	0.59231	
	$R_{\rm p} = 14.0\%$		b=5.628 Å	К	0	0	0.0453	0.639 <mark>5</mark> 1	
	$R_{\rm w} = 14.9\%$		c=5.647 Å	Nb	0.5	0	0.5251	0.606 <mark>8</mark> 4	58
	$R_{\rm exp} = 10.40\%$		<i>u</i> =0.012	Та	0.5	0	0.5251	0.242 <mark>5</mark> 8	
			v=0.021	01	0	0	0.4727	1.17 <mark>7</mark> 72	
			w=0.010	02	0.5	0.7535	0.2285	1.28250	
		P4mm	a=3.996 Å	Na	0	0	0	0.42083	
			c=3.974 Å	К	0	6.0	0	0.49908	
			<i>c/a</i> =0.994	Nb	0.5	0.5	0.492	0.65182	
			<i>u</i> =0.524	Та	0.5	0.5	0.492	0.24041	42
			<i>v</i> =-0.242	01	0.5	0.5	0.038	2.10799	
			w=0.071	02	0.5	0	0.539	2.73110	
4	$\chi^2 = 2.52$	Amm2	a=3.958 Å	Na	0	0	0.0453	0.60479	
	$R_{\rm p} = 16.2\%$		b=5.646 Å	К	0	0	0.0453	0.50137	
	$R_{\rm w} = 17.9\%$		c=5.644 Å	Nb	0.5	0	0.5251	0.64397	50
	$R_{exp} = 11.26\%$		<i>u</i> =0.018	Та	0.5	0	0.5251	0.27500	
			v=0.092	01	0	0	0.4727	1.27997	
			w=0.002	02	0.5	0.7535	0.2285	1.64498	
		P4mm	a=3.984 Å	Na	0	0	0	0.45192	
			c=3.987 Å	Κ	0	0	0	0.49912	
			c/a=1.000	Nb	0.5	0.5	0.492	0.80114	
			<i>u</i> =0.388	Та	0.5	0.5	0.492	0.31699	50
			v=0.233	01	0.5	0.5	0.038	2.18147	
			w=0.102	O2	0.5	0	0.539	1.07654	

5	$\chi^2 = 2.02$	Amm2	a=3.953 Å	Na	0	0	0.0453	0.66039	
	$R_{\rm p} = 16.6\%$		$b{=}5.630\text{\AA}$	Κ	0	0	0.0453	0.53941	
	$R_{\rm w} = 15.9\%$		$c{=}5.640\text{\AA}$	Nb	0.5	0	0.5251	0.57574	79
	$R_{exp} = 11.17\%$		<i>u</i> =0.076	Та	0.5	0	0.5251	0.29641	
			v=0.053	01	0	0	0.4727	1.07713	
			w=0.003	O2	0.5	0.7535	0.2285	2.26191	
		P4mm	a=3.997 Å	Na	0	0	0	0.59858	
			c=3.962 Å	Κ	0	0	0	0.59284	
			c/a=0.991	Nb	0.5	0.5	0.492	0.62353	21
			<i>u</i> =0.442	Та	0.5	0.5	0.492	0.20655	
			v=-0.374	01	0.5	0.5	0.038	1.98580	
			w=0.092	02	0.5	0	0.539	1.45685	

To confirm and complete the XRD analyses, Rietveld refinement was performed on all the ceramics to analyze the ratio of the O and T phases by fitting the XRD data using the FullProf program. The initial values of the cell parameters, lattice constants, space group, and atom functional positions were taken from corresponding reference patterns calculated from the Crystallography Open Database (COD). A structural model based on KaNaNbO<sub>3</sub> in tetragonal phase and space group P4mm and orthorhombic phase in space group Amm2 were used as starting models for refining the XRD data of the KNNT ceramics. The background was fit using a Chebyshev polynomial function, and the peak shape was described by a pseudo-Voigt function, (67) which is a linear combination of Lorentzian and Gaussian functions. To judge the quality of fit of the refinement, various parameters were calculated, including the profile reliability  $R_{\rm p}$ , the weighed pattern reliability  $R_{\rm wp}$ , the expected residual  $R_{\rm exp}$ , and the goodness of fit  $\chi^2$ . Figure 51 (a)-(d) shows the Rietveld refinement of the XRD patterns of all the KNNT ceramics in the 2-5 h range from 10 to 70°. As presented in Figure 51 (a)-(d), observational data ( $I_{obs}$ ) is defined by red hollow symbol, calculated pattern ( $I_{cal}$ ) is defined black solid line and different between ( $I_{obs}$ ) and (I<sub>cal</sub>) is defined by blue solid line. The quality of the fits was calculated as  $R_p \leq$ 16.6%,  $R_{\rm wp} \leq 17.9\%$ ,  $R_{\rm exp} \leq 11.26\%$ , and  $\chi^2 \leq 2.52$ , indicating good agreement between the observed and calculated intensity profiles of all the ceramics. The fitting results confirm that all the ceramics had two phases in coexistence, the orthorhombic and tetragonal phases. Table 3 presents the goodness-of-fit parameters, lattice parameters, atomic information, and percentage of each phase for all the ceramics sintered with different dwell times. The O:T ratio results reveal an increase of the

tetragonal phase and a decrease in the orthorhombic phase with increasing dwell time from 2 to 4 h. When using a dwell time of 4 h, the *O*:*T* ratio was 50:50. The phase fraction obtained in this ceramic lies in the morphotropic phase boundary (MPB) zone, which is crucial to achieve good electrical properties.



Figure 51 Typical Rietveld refinement analysis for KNNT ceramics at different dwell times: (a) 2, (b) 3, (c) 4 and (d) 5 h.

Figure 52 (a-d) presents the XPS spectra in the binding energy range from 0 to 1200 eV for the KNNT ceramics obtained using different dwell times. The standard C 1*s* signal (~285.0 eV) was applied to calibrate all the binding energies. The survey XPS spectrum shown in Figure 52 (a) reveals that all the ceramics were composed of K, Na, Nb, Ta, and O, confirming that KNNT ceramics were obtained. The high-resolution Nb 3*d* spectra for all samples (Figure 52) consisted of two wide peaks of Nb  $3d_{5/2}$  and Nb  $3d_{3/2}$ , corresponding to binding energy of ~209.67 and ~206.94 eV,

respectively. The structural splitting distance for all the compositions was ~2.73 eV, while the ratio of the Nb  $3d_{5/2}$  to Nb  $3d_{3/2}$  peak areas was ~1.53, indicating Nb<sup>5+</sup> (88, 89). Figure 52 (c) shows the high-resolution Ta 4f spectrum for all the samples. Two major characterized peaks corresponding to Ta  $4f_{5/2}$  and Ta  $4f_{7/2}$  were found at binding energy of ~27.63 eV and ~25.75 eV, respectively. The structural splitting distance for all the compositions was ~1.88 eV, and the ratio of the Ta  $4f_{7/2}$  and Ta  $4f_{5/2}$  peak areas was ~1.16, corresponding to  $Ta^{5+}$  (89, 90). These results provide evidence that the use of different dwell times did not change the valence states of the constituent elements of the KNNT ceramics. Next, the high-resolution O 1s spectra of all the samples are shown in Figure 52 (d), being fit with three peaks at binding energy of ~ 529.88 eV, ~ 531.62 eV, and ~ 533.52 eV, attributed to lattice oxygen (Nb-O), oxygen vacancies, and absorbed H<sub>2</sub>O, respectively (89, 91). Moreover, the concentration of oxygen vacancies for all the compositions was calculated from the area ratio II/(I + II + III) of the three peaks I, II, and III (Figure 52 (d)), (89, 92) yielding values of 33, 20, 25, and 29% for the dwell times of 2, 3, 4, and 5 h, respectively. The formation of oxygen vacancies can be explained by the volatilization of alkali-metal ions (positive charges) from the KNNT ceramics during sintering, leading to loss of oxygen (negatively charged ions) to maintain charge neutrality (93).



Figure 52 (a) The wide-range, high-resolution XPS spectrum of (b) Nb 3d, (c) Ta 4f, and (d) O 1s of KNNT ceramics as a function of dwell times.

Table	4 The ratio	of all eleme	nt spectrums	of the KN	NT ceramics	with different
	dwell time	es.				

	_									
Dwell time	Element (wt.%)									
( <b>h</b> )	С	0	Na	Та	Nb and Au	K				
2	03.41	09.68	04.39	35.23	40.28	07.00				
3	03.55	08.27	03.93	33.94	42.89	07.42				
4	03.88	09.14	03.89	36.56	39.53	07.00				
5	02.51	08.14	03.88	33.29	44.84	07.33				



Figure 53 SEM images and EDS spectrums of KNNT ceramics sintered at 1150°C for different dwell times: (a), (e) 2 h, (b), (f) 3 h, (c), (g) 4 h and (d), (h) 5



Figure 54 The measured and relative density of KNNT ceramics at a sintering temperature of 1150°C for the different dwell times.

SEM images of the KNNT ceramics obtained using different dwell times are shown in Figure 53 (a-d). The grains of all the ceramics showed irregular polyhedron shape, and the grain growth tended to be anisotropic. The average grain size of the ceramics gradually increased from 1.3 $\pm$ 0.28 to 2.6 $\pm$ 0.80  $\mu$ m with increasing dwell time from 2 to 4 h but then dropped, as shown in Figure 53. On the other hand, the porosity tended to decrease when the dwell time was increased from 2 to 4 h but then started to increase (Figure 53 (a-d)). Figure 53 (e-h) shows the energy-dispersive spectrometry (EDS) spectra of the KNNT ceramics obtained using different dwell times. C, O, Na, Ta, Nb, K, and Au elements were detected in all the ceramics. The Au signal resulted from the sample coating process applied for EDS. Table 4 presents the amount of each element calculated from their spectra for the KNNT ceramics obtained using different dwell times. Note that the quantity of Na continuously decreased as the dwell time was increased, while the other elements fluctuated but showed no upward or downward trend. Figure 54 shows the measured and relative density of the KNNT ceramics as a function of dwell time. Both values continuously increased with increasing dwell time from 2 to 4 h but then dropped. When using a dwell time of 4 h, the ceramics exhibited the highest measured density and relative density of  $5.28 \text{ g/cm}^3$  and 93.0%, respectively. It is well known that an optimal amount of oxygen vacancies and decreasing the number of pores leads to enhanced mass transport, resulting in increased grain size and density of the ceramics. The decrease in the average grain size and the density can be explained by the increase in the amount of pores, which hinder mass transfer and densification during the sintering process (94). For comparison, the density values of the KNNT ceramics (sintered at  $1150^{\circ}$ C for 4 h) obtained by this method are higher than values reported for hydrothermal approaches (90.5%) (50). The density results for the ceramics corresponded well with the SEM results.



Figure 55 Temperature dependent of the dielectric constant and loss of KNNT ceramics at a sintering temperature of 1150°C for the different dwell times: (a) 2, (b) 3, (c) 4 and (d) 5 h.

Figure 55 (a-d) shows the temperature dependence of the dielectric constant and dielectric loss for the KNNT ceramics obtained using different dwell times, measured in the temperature range from 30 to 400°C and at frequencies of 1, 10, and 100 *k*Hz. A frequency-independent response was observed for all the ceramics. Note that all the ceramics displayed two obvious phase-transition peaks above room temperature, corresponding to the orthorhombic-tetragonal ferroelectric phase transition  $(T_{\text{O-T}})$  and tetragonal-cubic paraelectric phase transition  $(T_{\text{C}})$ , respectively. The  $T_{\text{O-T}}$  and  $T_{\text{C}}$  values for the ceramics decreased from 94 to 89°C and from 230 to 228°C as the dwell time was increased, as seen in Table 5. The reduction of  $T_{O-T}$  and  $T_{\rm C}$  can be explained by distortions in the structure, corresponding to previous reports (95). The dielectric constant at room temperature ( $\varepsilon_R$ ) rise from 1041 to 1512 with increasing dwell time (Table 5). For, the dielectric constant at Curie temperature ( $\varepsilon_{\rm C}$ ) increased from 4237 to 5002 on increasing the dwell time from 1 to 4 h but then decreased for the dwell time of 5 h (Table 5). The values of the dielectric loss (tan  $\delta$ ) at room temperature  $(T_R)$  and at the Curie temperature  $(T_C)$  are presented in Table 5. When using a dwell time of 4 h, the KNNT ceramics showed the highest dielectric constant ( $\varepsilon_{\rm C} = 5002$ ) and low dielectric loss (tan  $\delta$  at  $T_{\rm R} = 0.032$  and tan  $\delta$  at  $T_{\rm C} =$ 0.035). This result may be explained by the large grain size, which increases the domain size and facilitates domain wall motion, (96) resulting in an increased dielectric constant for the KNNT ceramics obtained with a dwell time of 4 h. On the other hand, when the grain size becomes smaller, the grain boundaries thicken and the surface charge compensation layer increases, leading to a decrease of the dielectric constant (96, 97).

A modified Curie-Weiss law is proposed herein to explain the diffuseness of the ferroelectric phase transition (98) according to Eq. 21:

$$\frac{1}{\varepsilon} - \frac{1}{\varepsilon_C} = \left(T - T_C\right)^{\gamma} / C \tag{21}$$

where  $\varepsilon$  is the temperature-dependent dielectric constant, *C* is a Curie-like coefficient, and  $\gamma$  is the degree of diffuseness, having a value in the range from 1 to 2;  $\gamma = 1$ represents a normal ferroelectric whereas  $\gamma = 2$  describes a completely diffuse phase transition (98). The slopes of the fit curves of  $\ln(1/\varepsilon - 1/\varepsilon_{\rm C})$  versus  $\ln(T-T_{\rm C})$  at 1 kHz for the ceramics obtained using each dwell time were used to calculate the c values, as shown in Figure 56 (a-d). The  $\gamma$  values gradually increased from 1.550 to 1.655 with increasing dwell time (Figure 56), suggesting that the phase transition of these ceramics becomes more diffuse with increasing dwell time. The increase of the diffuseness of the phase transition in the samples may be caused by an increase in lattice disorder.



Figure 56 The plot of  $\ln(1/\epsilon \cdot 1/\epsilon_{\rm C})$  versus  $\ln(T - T_{\rm C})$  at 1 kHz for the KNNT ceramics at a sintering temperature of 1150°C for the different dwell times: (a) 2,

(b) 3, (c) 4 and (d) 5 h.



Figure 57 Polarization versus electric field (*P*-*E*) loops at room temperature for KNNT ceramics at a sintering temperature of 1150°C for 2-4 h.

 Table 5 Dielectric and ferroelectric properties of the KNNT ceramics sintered at 1150°C with the different dwell times.

Dwell	То-т	<i>T</i> c			$\tan \delta$ at	$\tan \delta$ at	Pr	Ec	Rsq
time (h)	(°C)	(°C)	ER	8C	TR	T <sub>C</sub>	(µC/cm <sup>2</sup> )	(kV/cm)	
2	94	230	1041	4237	0.030	0.038	10.81	8.07	0.78
3	92	229	1132	4786	0.037	0.035	17.00	9.13	0.91
4	91	228	1305	5002	0.032	0.035	18.50	9.04	0.96
-									
5	89	228	1512	4654	0.068	0.029	-	-	-
0	07	220	1012	1021	0.000	0.02)			

Figure 57 shows the polarization-electric field (*P-E*) hysteresis loops of the KNNT ceramics obtained using different dwell times, measured under an electrical field of 45 *k*V/cm and at a frequency of 1 Hz. Saturated *P-E* hysteresis loops were found for all the KNNT ceramics. It is seen that, with increasing dwell time, the  $P_r$  values increased from 10.81 to 18.50  $\mu$ C/cm<sup>2</sup>, while the  $E_C$  values changed only slightly. The remnant polarization ( $P_r$ ) and coercive field ( $E_C$ ) are presented as

functions of dwell time in Table 5. The increase of  $P_r$  at the dwell time of 4 h can be attributed to reaching the MPB and it's having the largest grain size, which makes the ferroelectric domains rotate more easily (99, 100). However, the ceramic obtained using a dwell time of 5 h could not be measured. This was mainly due to the high leakage current due to the porous microstructure and low density (101).

To analyze the ferroelectric characteristics of the KNNT ceramics, the degree of squareness ( $R_{sq}$ ) of the *P*-*E* loops (102) was calculated using Eq. 22:

$$R_{sq} = \frac{P_r}{P_s} + \frac{P_{1.1E_c}}{P_r}$$
(22)

where  $P_s$  is the saturation polarization and  $P_{1.1EC}$  is the polarization corresponding to 1.1 $E_{\rm C}$ . Theoretically,  $R_{\rm sq}$  should be equal to 2. This ideal  $R_{\rm sq}$  value indicates better homogeneity, uniformity in grain size, and good switching behavior of the ceramics (102). In this work, the  $R_{sq}$  values increased when the dwell time was increased, as seen in Table 5. The highest  $R_{sq}$  value of 0.96 was obtained for the ceramics with a dwell time of 4 h, suggesting that the use of an optimum dwell time during sintering can improve the microstructure and electrical properties of KNNT ceramics. According to the discussion above, the KNNT ceramics obtained using the optimum firing condition (1150°C for 4 h) exhibited good electrical performance. This phenomenon can be attributed to two main factors. First, the occurrence of a morphotropic phase boundary (MPB) zone of coexisting O + T phases at a ratio of O:T of 50:50, resulting in instability of the polarization state, so the polarization direction can be easily rotated by an electric field. Second, this ceramic had a welldeveloped microstructure, the highest density, and large grain size, which enhance the domain variants, while the trapped space charges at grain boundaries were reduced (14). The deterioration of the electrical properties of the ceramics produced under the other conditions was caused by low density and porous structures forming at grain boundaries, leading to high electrical conductivity.

## 2. The influences of Cs<sup>+</sup> substitution and direct doping on the phase evolution, microstructure and electrical properties of KNNT ceramics

Figure 58 shows the XRD patterns of the  $K_{0.5-x}Cs_xNNT$  (Figure 58 a(I-III)) and KNNT-xCs ceramics (Figure 58 b(I-III)). It can be observed that all compositions exhibited a pure perovskite phase and no trace of any secondary phase was detected. To determine the phase formation, the XRD patterns of all samples at  $2\theta$  around ~39° and ~45° were zoomed and shown in Figure 58 a(II-III) - b(II-III). Generally, an orthorhombic (O) structure (JCPDS file no 01-071-0946) exhibits characteristic of dual  $(102)/(120)_0$  peaks around ~39° and dual  $(022)/(200)_0$  peaks around ~45°. In the case of a tetragonal (T) structure (JCPDS file no 01-071-0945), there is a characteristic of a single  $(111)_T$  peak around ~39° and dual  $(002)/(200)_T$  peaks around ~45°. The undoped KNNT ceramic with x=0 showed a diffraction peak with a broad and non-symmetry peak around ~39° (Figure 58 a(II) - b(II)) and dual peaks around ~  $45^{\circ}$  (Figure 58 a(III) - b(III)). Compared with the undoped KNNT ceramic, the ceramics with Cs<sup>+</sup> had peaks that became more sharp and non-symmetrical around ~39° (Figure 58 a(II) - b(II)) and showed three peaks around ~45° (Figure 58 a(III) b(III)) for both the  $K_{0.5-x}Cs_xNNT$  and KNNT-xCs ceramics with x=0.01-0.04. This indicated that the phase formation in all samples had coexisting O and T phases. Moreover, it can be seen that the diffraction peaks at  $\sim 39^{\circ}$  and  $\sim 45^{\circ}$  of K<sub>0.5-x</sub>Cs<sub>x</sub>NNT ceramics moving slightly to lower  $2\theta$  angles with increasing x doping (Figure 58 a(II-III)), because of the substitution of  $K^+$  (ionic radius 1.64 Å) by the larger  $Cs^+$  (ionic radius 1.88 Å) in the ABO<sub>3</sub> structure lead to expansion of the crystal lattice (103, 104). While the KNNT-xCs ceramics diffraction peaks at  $\sim 39^{\circ}$  and  $\sim 45^{\circ}$  moving to lower  $2\theta$  angles as the x content increased up to 0.01 (Figure 58 b(II-III)), and then returned to positions close to the peaks at x=0, indicating the limits of solubility of Cs<sup>+</sup> in the KNNT lattice.



Figure 58 XRD patterns of the (a) K<sub>0.5-x</sub>Cs<sub>x</sub>NNT and (b) KNNT-xCs ceramics with different x.

In order to confirm and complete the XRD analyses, Rietveld refinement was performed on all the ceramics by fitting the XRD data with the Fullprof program. The initial values of the cell parameters, lattice constants, space group and atom functional positions were taken from the corresponding reference patterns calculated from the Crystallography Open Database (COD). A structural model based on KaNaNbO<sub>3</sub> with a tetragonal phase (*T*), with a *P4mm* space group, and an orthorhombic phase (*O*), with an *Amm*2 space group, were used as the starting models for refining the K<sub>0.5-x</sub>Cs<sub>x</sub>NNT and KNNT-xCs ceramics' XRD data. The examples of the final output from the Rietveld refinement are displayed in Figure 59 (a)-(e). As presented in Figure 59 (a)-(e), observational data ( $I_{obs}$ ) is defined by red hollow symbol, calculated pattern ( $I_{cal}$ ) is defined black solid line and different between ( $I_{obs}$ ) and ( $I_{cal}$ ) is defined by blue solid line. It was found that the calculated quality of the fits were  $R_p \le 12.10\%$ ,

 $R_{wp} \le 12.90\%$ ,  $R_{exp} \le 7.99\%$  and  $\chi^2 \le 2.72$  (Table 6), suggesting fine agreement between the observed and refined intensity profiles for all compositions. The fitting outcome approved that all ceramics include coexisting *O* and *T* phases. For both the K<sub>0.5-</sub> <sub>x</sub>Cs<sub>x</sub>NNT and KNNT-xCs ceramics, the proportion of *O*:*T* showed an increase of the *O* while the *T* reduced with rising x. The volume cell and phase percentage of all compositions are listed in Table 6. The average volume cell of K<sub>0.5-x</sub>Cs<sub>x</sub>NNT ceramics tends to increase when increasing x. While for the KNNT-xCs ceramics, the average volume cell increased when x increases up to 0.01 and then decreased. Figure 59 (f) demonstrates the percentage of the tetragonal phase of the K<sub>0.5-x</sub>Cs<sub>x</sub>NNT and KNNTxCs ceramics with various x.





Figure 59 Rietveld refinement on XRD patterns of the KNNT (a), the K<sub>0.5-</sub> <sub>x</sub>Cs<sub>x</sub>NNT with x=0.01 (b) and x=0.03 (c), and the KNNT-xCs ceramics with x=0.01 (d) and x=0.03 (e); (f) the percentage of orthorhombic phase of the samples with different x.

Sampla	<b>Refine parameters</b>	Volume	cell (Å <sup>3</sup> )	Phase percentage (%)		
Sample		Amm2	P4mm	Amm2	P4mm	
VNNT	$\chi^2 = 2.49, R_p = 11.0\%$	126.22	63.30	50	50	
KININI	$R_{wp}=12.6\%, R_{exp}=7.98\%$					
	$\chi^2 = 1.85, R_p = 9.62\%$	126.39	63.40	53	47	
K0.49C80.011N1N1	$R_{wp}=10.7\%, R_{exp}=7.83\%$					
Ko to Cao on NNT	$\chi^2 = 1.91, R_p = 9.26\%$	126.47	63.44	54	46	
K <sub>0.48</sub> CS <sub>0.02</sub> ININ I	$R_{wp}=10.9\%, R_{exp}=7.86\%$					
KCoNNT	$\chi^2 = 2.23, R_p = 10.2\%$	126.48	63.57	56	44	
K0.47CS0.031N1N1	$R_{wp} = 11.8\%, R_{exp} = 7.89\%$					
	$\chi^2 = 1.72, R_p = 9.31\%$	126.48	63.75	59	41	
K0.46CS0.041NIN I	$R_{wp} = 10.1\%, R_{exp} = 7.71\%$					
KNNT-0.01Cs	$\chi^2 = 2.32, R_p = 11.4\%$	126.31	63.44	52	48	
MUU1-0.01C3	$R_{wp}=12.2\%, R_{exp}=7.99\%$					
KNNT-0.02Ce	$\chi^2 = 2.54, R_p = 11.1\%$	126.15	62.56	53	47	
KINI -0.02C3	$R_{wp}=12.3\%, R_{exp}=7.73\%$					
KNNT 0.03Cs	$\chi^2 = 2.72, R_p = 12.1\%$	126.03	62.52	54	46	
KININI-0.03CS	$R_{wp}=12.9\%, R_{exp}=7.81\%$					
KNNT 0.04Ca	$\chi^2 = 2.19, R_p = 9.91\%$	124.98	62.60	56	44	
KININ I -0.04CS	$R_{wp} = 11.3\%, R_{exp} = 7.64\%$					

Table6 Goodness of fit, volume cell and phase percentage of the KNNTceramics with different Cs+ substitutional and additional doping.

The SEM images of the K<sub>0.5-x</sub>Cs<sub>x</sub>NNT and KNNT-xCs ceramics with x=0-0.04 are shown in Figure 60 (a)-(i). The grains of all the ceramics exhibited a rather rectangular shape. As seen in Figure 60 (a), it was found that the undoped KNNT ceramic showed very dense, unclear grain boundaries and small pores. When doped with both substitutional and additional Cs<sup>+</sup>, the grain boundaries become clear and pores were observed. The porosity of both the K<sub>0.5-x</sub>Cs<sub>x</sub>NNT and KNNT-xCs ceramics increased as x increased. The average grain size of the KNNT ceramic was about 2.3±0.49  $\mu$ m (Figure 60 (a)). For the K<sub>0.5-x</sub>Cs<sub>x</sub>NNT ceramics, the average grain size deceased to about 1.3±0.24  $\mu$ m when x increased up to 0.04 (Figure 60 (b)-(e)). Similarly, the average grain size of the KNNT-xCs ceramics deceased to about 1.5±0.14  $\mu$ m when x = 0.04 (Figure 60 (b)-(f-i)). Figure 61 shows the measured density of the K<sub>0.5-x</sub>Cs<sub>x</sub>NNT and KNNT-xCs ceramics as a function of x. The density value of both the K<sub>0.5-x</sub>Cs<sub>x</sub>NNT and KNNT-xCs ceramics decreased upon increasing x. Comparing the results of Figure 61, it was observed that the KNNT-xCs ceramics had a higher density than that of  $K_{0.5-x}Cs_xNNT$  ceramics. The reduction in the average grain size and the density can be explained by the increasing number of pores, which hinders mass transfer and densification during the sinter process (94, 105). In addition, it is well known that the alkaline elements (K and Na) in KNN-based ceramics are volatilize during the sintering process, due to their low boiling points, which results in deteriorate of the sample density (104, 106). The energy dispersive X-ray spectrometer (EDS) technique was used to investigate the amount of each element for both the  $K_{0.5-x}Cs_xNNT$  and KNNT-xCs ceramics with x=0.01 and 0.04, as seen in Figure 62 (a)-(d). O, Na, Ta, Nb, K, Cs and Au elements were detected in all compositions. The Au spectrum is due to the sample coating process of the EDS. It was found that the quantity of Na and K in the  $K_{0.5-x}Cs_xNNT$  ceramics with x=0.01 was about 4.57 and 7.80 wt.%, and at x=0.04, it was about 4.63 and 6.88 wt.% (Figure 62 (a)-(b)). In the case of KNNT-xCs ceramics with x=0.01, the amount of Na and K was about 5.25 and 7.72 wt.%, and at x=0.04 it was about 5.74 and 8.03 wt.% (Figure 62 (c)-(d)). Here it can be seen that K and Na elements in the ceramics with Cs<sup>+</sup> substitutional doping is less than for the additional doping samples, which might be the reason for the  $K_{0.5-x}C_{sx}NNT$  ceramics lower density, than of KNNT-xCs ceramics. To inspect the distribution of each element in the specimens, the surface element mapping of both the  $K_{0.5-x}Cs_xNNT$  and KNNT-xCs ceramics with x=0.04 were carried out, as seen in Figure 63 (a)-(b). It was observed that K, Na, Nb, Ta, O and Cs elements of both substitutional and additional doping ceramics were uniformly distributed throughout the microstructure.



Figure 60 SEM images of the (a) KNNT ceramic, (b-e) K<sub>0.5-x</sub>Cs<sub>x</sub>NNT ceramics with x=0.01-0.04 and (f-i) KNNT-xCs ceramics with x=0.01-0.04.



Figure 61 Measured density of the K0.5-xCsxNNT and KNNT-xCs ceramics as a



Figure 62 EDS spectra of the K<sub>0.5-x</sub>Cs<sub>x</sub>NNT ceramics with (a) x=0.01, (b) x=0.04 and the KNNT-xCs ceramics with (c) x=0.01 and (d) x=0.04.



Figure 63 Elemental mapping of (a) the K<sub>0.5-x</sub>C<sub>5x</sub>NNT ceramic with x=0.04 and (b) the KNNT-xCs ceramic with x=0.04.

The dielectric constant and dielectric loss of the K<sub>0.5-x</sub>Cs<sub>x</sub>NNT and KNNT-xCs ceramics with different x, measured at 1 *k*Hz are displayed in Figure 64 (a)-(b). Two phase transitions were observed in all samples, which corresponded to the orthorhombic ferroelectric-tetragonal ferroelectric phase transition at ~ 85°C ( $T_{\text{O-T}}$ ) and the tetragonal ferroelectric-cubic paraelectric phase transition at ~ 220°C ( $T_{\text{C}}$ ).  $T_{\text{O-T}}$  and  $T_{\text{C}}$  were determined using the interception of the two tangents on both sides of the peak and the temperature at the maximum value of the dielectric constant, respectively. For, both the K<sub>0.5-x</sub>Cs<sub>x</sub>NNT and KNNT-xCs ceramics,  $T_{\text{O-T}}$  and  $T_{\text{C}}$  can be explained by lattice distortions in the crystal structure, corresponding to previous reports (95, 107). The dielectric constant at room temperature ( $\varepsilon_{\text{R}}$ ) and at the

Curie temperature ( $\varepsilon_C$ ) of all compositions are listed in Table 7. The  $\varepsilon_R$  and  $\varepsilon_C$  of the undoped KNNT ceramic were around 1372 and 5115. Cs<sup>+</sup> doping, either substitutional and additional doping, strongly decreased the  $\varepsilon_{\rm R}$  and  $\varepsilon_{\rm C}$ . As shown in Figure 64 (a) and (b), higher x results in lower  $\varepsilon_R$  and  $\varepsilon_C$ . The highest of the  $\varepsilon_R$  and  $\varepsilon_C$ values in undoped KNNT ceramic can be explained by well-developed microstructure, high density, and the optimum proportion of O:T phases (50:50) leading to enhanced the polarization within the material (108). While, the deterioration of the dielectric properties of the ceramics with Cs<sup>+</sup> was caused by the low density and porous structures forming at the grain boundaries, leading to a high electrical conductivity (109). For comparison in Table 7, one can see that  $\varepsilon_{\rm C}$  values of the  $K_{0.5-x}Cs_xNNT$  ceramics with x=0.01-0.04 were only about 4746-3423, but that of the KNNT-xCs ceramics with x=0.01-0.04 were about 4797-4118. Thus, KNNT-xCs ceramics had much higher dielectric constants than K<sub>0.5-x</sub>Cs<sub>x</sub>NNT ceramics, which may be attributed to the higher density value of KNNT-xCs ceramics (Figure 61). The dielectric loss (tan  $\delta$ ) at  $T_{\rm R}$  and  $T_{\rm C}$  of the KNNT ceramics with Cs<sup>+</sup> substitutional and additional doping are shown in Table 7.





Figure 64 Temperature dependence of the dielectric constant and dielectric loss for the (a) K<sub>0.5-x</sub>Cs<sub>x</sub>NNT and (b) KNNT-xCs ceramics with different x.

Figure 65 (a-b) illustrates the polarization-electric field (*P-E*) hysteresis loops of the  $K_{0.5-x}Cs_xNNT$  and KNNT-xCs ceramics with different x, measured under an electrical field of 20 *k*V/cm and at a frequency of 1 Hz. The normal *P-E* hysteresis loop was found only in the undoped KNNT composition, while the rest were lossy loops. The undoped KNNT ceramic showed a well-saturated *P-E* hysteresis loop. When doped both substitutional and additional with Cs<sup>+</sup>, a leakage current was created. Both  $K_{0.5-x}Cs_xNNT$  and KNNT-xCs ceramics showed the leakage current that increased as x increased from 0.01 to 0.03. The remnant polarization ( $P_r$ ) and coercive field ( $E_c$ ) of K<sub>0.5-x</sub>Cs<sub>x</sub>NNT and KNNT-xCs ceramics with different x are listed in Table 7. The  $P_r$  and  $E_c$  values of KNNT ceramics were ~9.7  $\mu$ C/cm<sup>2</sup> and ~7.6 kV/cm. For the <sub>K0.5-x</sub>Cs<sub>x</sub>NNT ceramics, the  $P_r$  and  $E_c$  increased to 40.3  $\mu$ C/cm<sup>2</sup> and 14.0 kV/cm when x increased up to 0.03. Likewise, the  $P_r$  and  $E_c$  of KNNT-xCs ceramics tended to increase, up to 39.6  $\mu$ C/cm<sup>2</sup> and 13.7 kV/cm when x increased up to 0.03. Except for the undoped KNNT composition, all  $P_r$  and  $E_c$  values were incorporated with the results of leakage current, not only from their ferroelectric domain responses. However, both the K<sub>0.5-x</sub>Cs<sub>x</sub>NNT and KNNT-xCs ceramics at x=0.04 could not be measured. This was mainly due to the high leakage current caused from the porous microstructure and low density.

 Table 7 Dielectric and ferroelectric properties of KNNT ceramics as a function of Cs<sup>+</sup> additional and substitutional doping.

samples	<i>Т</i> о-т (°С)	Tc (°C)	ER	tan δat T <sub>R</sub>	EC	tan δat Tc	Pr (µC/cm <sup>2</sup> )	Ec (kV/cm)
KNNT	90	221	1372	0.23	5115	0.06	9.7	7.6
K <sub>0.49</sub> Cs <sub>0.01</sub> NNT	83	217	1246	0.36	4746	0.07	23.7	10.4
K <sub>0.48</sub> Cs <sub>0.02</sub> NNT	85	216	1148	0.32	4284	0.04	33.5	14.0
K <sub>0.47</sub> Cs <sub>0.03</sub> NNT	83	216	1138	0.36	4242	0.05	40.3	14.0
K <sub>0.46</sub> Cs <sub>0.04</sub> NNT	84	220	1179	0.54	3423	0.05	-	-
KNNT-0.01Cs	89	224	1122	0.33	4797	0.06	32.6	12.5
KNNT-0.02Cs	83	218	988	0.10	4441	0.05	31.3	14.2
KNNT-0.03Cs	81	217	995	0.17	4374	0.05	39.6	13.7
KNNT-0.04Cs	80	215	946	0.13	4118	0.05		-



Figure 65 Ferroelectric hysteresis (*P-E*) loops at room temperature for the (a) K<sub>0.5-x</sub>Cs<sub>x</sub>NNT and (b) KNNT-xCs ceramics with different x.

In summary, it is pointed out that the monitoring of phase evolution, density and electric behaviors for both  $K_{0.5-x}Cs_xNNT$  and KNNT-xCs ceramics lead to the similar trend. The density and electrical properties of the KNNT-xCs samples were greater than the  $K_{0.5-x}Cs_xNNT$  samples. Many studies have revealed that direct doping of element or compounds into KNN-based ceramics causes increment of liquid phase and oxygen vacancy, leading to enhance mass transport, resulting in improved density and electric behaviors of samples (84, 110).

Figure. 66 depicts the XRD patterns of the surface region of the KN<sub>0.5-x</sub>Li<sub>x</sub>NT (Figure. 66 a(I-III)) and KNNT-xLi ceramics (Figure. 66 b(I-III)) with different x. All compositions exhibited a pure perovskite phase and no trace of any secondary phase was identified. This suggests that Li<sup>+</sup> has fully diffused into the KNNT lattice, to form solid solution. Further scrutiny of the phase composition is seen in the enlarged XRD diagrams at  $2\theta$  around  $\sim 39^{\circ}$  and  $\sim 45^{\circ}$  in Figure. 66 a(II-III) - b(II-III). Ceramics with an orthorhombic (O) structure (JCPDS file no 01-071-0946) exhibits traits of dual  $(102)/(120)_{0}$  peaks around 39° and dual  $(022)/(200)_{0}$  peaks around 45°. In the event of a tetragonal (T) structure (JCPDS file no 01-071-0945), there is a single  $(111)_T$ peak around 39° and dual  $(002)/(200)_T$  peaks around 45°. In this experiment, the undoped KNNT ceramic with x=0 showed a diffraction peak with a broad and nonsymmetry peak around 39° (Figure. 66 a(II) - b(II)) and dual peaks around 45° (Figure. 66 a(III) - b(III)). For the ceramics with  $Li^+$  doping (x=0.01-0.04), the peaks around 39° became sharper and non-symmetrical (Figure. 66 a(II) - b(II)) and three peaks appeared around 45° (Figure. 66 a(III)-b(III)). This indicated that the phase structure in all samples had coexisting O and T phases, a behavior similar to Li doped KNN ceramics [16]. Moreover, the diffraction peaks at  $\sim 39^{\circ}$  and  $\sim 45^{\circ}$  (Figure. 66 a(II-III)) of the KN<sub>0.5-x</sub>Li<sub>x</sub>NT ceramics moving slightly to higher  $2\theta$  angles as x increases from 0 to 0.02, indicating the contraction of the crystal lattice. This can be attributed to the small ionic radii of Li<sup>+</sup> (1.15 Å) replacing larger Na<sup>+</sup> (1.39 Å) in the ABO<sub>3</sub> structure. After that, the  $2\theta$  angles of the diffraction peaks shifted lower when the x increased up to 0.04 (Figure. 66 a(II-III)). The increasing of the unit cell volume can be caused by the Li<sup>+</sup> ions partially entering the B-sites [Nb<sup>5+</sup> (0.64 Å) or Ta<sup>5+</sup> (0.64 Å)], this may be caused by the solubility limits of Li<sup>+</sup> ions in A-sites (111). For the KNNT-xLi ceramics, the diffraction peaks at  $\sim 39^{\circ}$  and  $\sim 45^{\circ}$  (Figure. 66 b(II-III)) moving slightly to lower  $2\theta$  angles with rising x, indicating that the Li<sup>+</sup> substituted into B-sites and the unit cell of the structure expands.



Figure 66 Room temperature XRD patterns of the (a) KN0.5-xLixNT and (b) KNNT-xLi ceramics with various x.

To further inspected the XRD analysis, Rietveld refinement was used on all the ceramics to fit the XRD data using the Fullprof software. The Crystallography Open Database (COD) is the standard information source for the initial values for space groups, lattice constants and atom functional positions. The XRD data of the  $KN_{0.5-x}Li_xNT$  and KNNT-xLi ceramics were refined using a structural model based on KaNaNbO<sub>3</sub> with a tetragonal phase (*T*), with a *P4mm* space group, and an orthorhombic phase (*O*), with an *Amm*2 space group. Figure. 67 (a)-(e) depicts the final output from the Rietveld refinement. As shown in Figure. 67 (a)-(e), observational data ( $I_{obs}$ ), represented by the red hollow symbol, calculated patterns ( $I_{cal}$ ) are represented by the black solid line and the different ( $I_{obs}$ ) and ( $I_{cal}$ ) is presented by the blue solid line. The quality values, lattice parameters, volume cell and phase percentage of all compositions are listed in Table 8. It was found that the calculated quality of the fits were  $R_p \le 11.70\%$ ,  $R_{wp} \le 12.60\%$ ,  $R_{exp} \le 7.98\%$  and  $\chi^2 \le 2.62$  (Table 8), indicating fine agreement between the observed and calculated intensity profiles for all compositions. The fitting outcome showed that all ceramics had two phases in coexistence, the tetragonal and orthorhombic phases. For both the KN<sub>0.5-x</sub>Li<sub>x</sub>NT and KNNT-xLi ceramics, the proportion of *T*:*O* showed an increase of the *T* while the *O* declined with rising x (Table 8). Figure 67 (f) demonstrates the percentage of the tetragonal phase of the KN<sub>0.5-x</sub>Li<sub>x</sub>NT and KNNT-xLi ceramics with various x.



Figure 67 Rietveld refinement on XRD patterns of the KNNT (a), the KN<sub>0.5</sub>. <sub>x</sub>Li<sub>x</sub>NT with x=0.01 (b) and x=0.03 (c), and the KNNT-xLi ceramics with x=0.01 (d) and x=0.03 (e); (f) the percentage of tetragonal phase of the samples with various x.

Samuelas	Define recorded	Lattice pa	rameters	Phase percentage (%)		
Samples	Refine parameters	P4mm	Amm2	P4mm	Amm2	
	$\chi^2 = 2.49, R_p = 11.0\%$	a=3.974 Å,	a=3.961 Å,	50	50	
KNNT	$R_{wp} = 12.60\%$ ,	c=4.008 Å,	b=5.656 Å,			
	Rexp=7.98%	c/a=1.008	c=5.634 Å			
KN0 49L in 01NT	$\chi^2 = 1.88, R_p = 9.70\%$	a=3.999,	a=3.961 Å,	53	47	
1110.49240.01111	$R_{wp}=10.40\%$ ,	c=3.957,	b=5.629 Å,			
	Rexp=7.56%	c/a=0.989	c=5.646 Å			
	$\chi^2 = 2.23, R_p = 9.63\%$	a=3.996 Å,	a= 3.960 Å,	58	42	
KN0.48Li 0.02NT	$R_{wp}=10.90\%$ ,	c=3.953 Å,	b=5.642 Å,			
	$R_{\rm exp} = 7.32\%$	c/a=0.989	c=5.631 Å			
KN0 47L i 0.02NT	$\chi^2 = 2.13, R_p = 10.50\%$	a=3.965  Å,	a=3.967 Å,	68	32	
<b>IXI (</b> 0.47 <b>LI</b> 0.03 <b>I</b> ( <b>I</b>	$R_{wp}=11.30\%$ ,	c=4.015 Å,	b=5.672 Å,			
	R <sub>exp</sub> =7.78%	c/a=1.012	c=5.637 Å			
	$\gamma^2 - 2.62 R - 11.70\%$	a-3 966 Å	a = 3.964  Å	77	23	
KN0.46Li 0.04NT	$\chi = 2.02, R_p = 11.7070$	c=4.018 Å	h=5.683 Å		25	
	$R_{wp} = 12.00\%$	c/a=1.013	c = 5.603  Å			
	Rexp-1.1970	0/4-1.015	C- 5.042 H			
	$\gamma^2 = 1.63, R_p = 8.91\%$	a=3.969 Å,	a=3.957 Å,	57	43	
KNNT-0.01Li	$R_{\rm wn}=9.98\%$ , $R_{\rm exn}=7.82\%$	c=3.997 Å,	b=5.644 Å,			
	11wp=9.9070, 11exp=7.0270	c/a=1.007	c=5.626 Å			
KNINT O OOL .	$\chi^2 = 2.04, R_p = 9.71\%$	a= 3.963,	a=3.957 Å,	64	36	
KININT-0.02L1	$R_{wp}=11.00\%$ ,	c=4.000,	b=5.645 Å,			
	Rexp=7.67%	c/a=1.009	c=5.625 Å			
	$x^2 - 2.39 R_{-11} 60\%$	a=3 951 Å	a=3 950 Å	70	30	
KNNT-0.03Li	$\chi = 2.57, \text{ Kp} = 11.00\%,$	c=3.994  Å	h=5.632 Å	10	50	
	$R_{wp} = 12.10\%$	c/a=1.010	c=5.650  Å			
	Kexp-7.0170	0/ 4 - 1.010	0-5.05071			
	$\chi^2 = 2.31, R_p = 11.30\%$	a=3.950 Å,	a=3.949 Å,	74	26	
KNNT-0.04Li	$R_{wp} = 11.80\%$ ,	c=3.995 Å,	b=5.637 Å,			
	R <sub>exp</sub> =7.78%	c/a=1.011	c=5.645 Å			

Table 8 The goodness of fit parameters, lattice parameters and the percentage ofphases for the KN0.5-xLixNT and KNNT-xLi ceramics as a function of x.



Figure 68 SEM micrographs of the (a) KNNT ceramics, (b-e) KN<sub>0.5-x</sub>Li<sub>x</sub>NT ceramics with x=0.01-0.04 and (f-i) KNNT-xLi ceramics with x=0.01-0.04.

The SEM images of the KN<sub>0.5-x</sub>Li<sub>x</sub>NT and KNNT-xLi ceramics with x=0-0.04 are shown in Figure. 68 (a)-(i). The ceramic grains presented a rather rectangular shape, with a non-uniform grain size distribution as the growth of the grains was anisotropic for all compositions. As seen in Figure. 68 (a), it was found that the unmodified KNNT ceramic showed very dense, unclear grain boundaries and small pores. When doped with both substitutional and additional Li<sup>+</sup>, the grain boundaries become clear and pores were still observed. According to Zhen's study (84), the porous microstructure is primarily caused of the evaporation of the organic substances and alkali elements (K and Na). Chemical compositions of the KN<sub>0.5-x</sub>Li<sub>x</sub>NT and KNNT-xLi ceramics (x=0, 0.02 and 0.04) were measured with an energy dispersive X-ray spectrometer (EDS) as summarized in Table 9. The elements of K, Na, Nb, Ta, O and Au were exposed. All specimens display a slight fluctuation in composition. The quantity of K and Na are very low as compared to the chemical formula, owing to their volatility. The average grain size of the unmodified KNNT ceramic was about 2.1±0.54  $\mu$ m (Figure. 68 (a)). For the KN<sub>0.5-x</sub>Li<sub>x</sub>NT ceramics with x=0.01-0.04, the average grain sizes were in the range of  $1.4\pm0.30$  to  $2.2\pm0.34$  µm (Figure. 68 (b)-(e)). And the average grain size of the KNNT-xLi ceramics with x=0.01-0.04 was in the range of 2.1±0.44 to 2.6±0.38  $\mu$ m (Figure. 68 (b)-(f-i)). The density value of both the KN<sub>0.5-x</sub>Li<sub>x</sub>NT and KNNT-xLi ceramics decreased upon increasing x, as seen in Figure 69.





Figure 69 The measured density of the KN<sub>0.5-x</sub>Li<sub>x</sub>NT and KNNT-xLi ceramics as a function of x.

## Table 9 Chemical compositions of the KN<sub>0.5-x</sub>Li<sub>x</sub>NT and KNNT-xLi ceramics as a function of x.

Samples	Elements (wt.%)								
	K	Na	Nb and Au	Та	0				
KNNT	8.10	5.92	44.41	25.04	16.53				
$KN_{0.48}Li_{0.02}NT$	7.77	5.41	44.16	26.74	15.92				
$KN_{0.46}Li_{0.04}NT$	7.48	5.05	42.96	31.75	12.77				
KNNT-0.02Li	7.97	5.53	47.30	21.39	17.82				
KNNT-0.04Li	7.82	3.19	50.01	24.23	17.74				



Figure 70 Temperature dependence of the dielectric constant and the loss tangent of the (a) KN<sub>0.5-x</sub>Li<sub>x</sub>NT and (b) KNNT-xLi ceramics with various x, measured at 1 *k*Hz.

The dielectric constant and dielectric loss of the KN<sub>0.5-x</sub>Li<sub>x</sub>NT and KNNT-xLi ceramics with different x are displayed in Figure 70 (a)-(b). The unmodified KNNT ceramic had two-phase transition temperatures, associate with the ferroelectric orthorhombic-tetragonal phase transition at ~90°C ( $T_{\text{O-T}}$ ) and ferroelectric tetragonal-paraelectric cubic phase transition at ~221°C (Curie temperature,  $T_{\text{C}}$ ). When doped with substitutional Li<sup>+</sup>,  $T_{\text{O-T}}$  of the KN<sub>0.5-x</sub>Li<sub>x</sub>NT ceramic decreased to ~77°C when x=0.01. For the KNNT-xLi ceramics,  $T_{\text{O-T}}$  decreased to ~60 °C when x=0.02. While
the KN<sub>0.5-x</sub>Li<sub>x</sub>NT ceramics at x=0.02-0.04 and KNNT-xLi ceramics at x=0.03-0.04, saw the  $T_{\text{O-T}}$  moved to temperatures too low to measure. On the other hand, the  $T_{\text{C}}$  of both KN<sub>0.5-x</sub>Li<sub>x</sub>NT and KNNT-xLi ceramics shifted to higher temperatures ~266 and 253°C, respectively (Table 10), when x increased up to 0.04. The incremental increase of the  $T_{\rm C}$  may be attributed to the increased tetragonal distortion, as seen by Long et al. (16). The dielectric constant at room temperature ( $\varepsilon_R$ ) and the Curie temperature  $(\varepsilon_{\rm C})$  of all compositions are summarized in Table 10. The  $\varepsilon_{\rm C}$  of the undoped KNNT ceramic was around 5115. With x increasing up to 0.02, the  $\varepsilon_{\rm C}$  values of the KN<sub>0.5-</sub>  $_xLi_xNT$  ceramics tended to decrease and then increased at x=0.03. When x>0.03, the  $\varepsilon_{\rm C}$  value dropped again (Table 10). For the KNNT-xLi ceramics, the  $\varepsilon_{\rm C}$  values declined with rising x, up to 0.01 and then increased at x=0.02. With x>0.02, the  $\varepsilon_{\rm C}$  values dropped again. However, the in-depth explanation for the changing of the  $\varepsilon_{\rm C}$  values could not be exactly determined. A possible explanation might be due to the complexity and fluctuation of the studied compositions (112, 113). For comparison in Table 10, one can see that  $\varepsilon_{\rm C}$  values of the KN<sub>0.5-x</sub>Li<sub>x</sub>NT ceramics with x=0.01-0.04 were only about 4141-3540, but that of the KNNT-xLi ceramics with x=0.01-0.04 were about 4595-3844. Thus, KNNT-xLi ceramics had much higher dielectric constants than KN<sub>0.5-x</sub>Li<sub>x</sub>NT ceramics. The deterioration of the dielectric constants of the specimens with Li<sup>+</sup> was brought about by the low density and porous structures forming at the grain boundaries, leading to an elevated electrical conductivity. The dielectric loss (tan  $\delta$ ) at room temperature (T<sub>R</sub>) and T<sub>C</sub> of the KNNT ceramics with Li<sup>+</sup> substitutional and additional doping are shown in Table 10. The tan  $\delta$  at T<sub>R</sub> of unmodified KNNT ceramics was about 0.23. The KN<sub>0.5-x</sub>Li<sub>x</sub>NT and KNNT-xLi ceramics were found in the range of 0.21-0.59 and 0.23-0.43, respectively. The high tan  $\delta$  at  $T_{\rm R}$  and at a temperature above  $T_{\rm C}$ , which was related to high concentration flaws in the samples. The defect equations from the substitution of Li<sup>+</sup> in a KNNT lattice at A-sites (A<sub>2</sub>O; A=K and Na) or B-sites (B<sub>2</sub>O<sub>5</sub>; B=Nb and Ta) can be written as (23) and (24), respectively.

$$Li_2 O \xrightarrow{A_2 O} 2Li_A^{\times} + O_O^{\times}$$
(23)

$$Li_2 O \xrightarrow{B_2 O_5} 2Li_B^{""} + O_O^{\times} + 4V_O^{\bullet\bullet}$$

$$\tag{24}$$



Figure 71 Room-temperature *P-E* hysteresis loops of the KN<sub>0.5-x</sub>Li<sub>x</sub>NT ceramics with x=0.01-0.04.

The polarization-electric field (*P-E*) hysteresis loops with standard polarization hysteresis loops and remanent polarization hysteresis loops of the  $KN_{0.5-x}Li_xNT$  samples with different x are plotted in Figure 71 (a)-(e). The standard polarization hysteresis loops display a typical *P-E* loop and leakage current for all compositions. The *P-E* loops were slimmer with rising x. The appearance of leakage

currents in the samples may be attributed to a high concentration of flaws and a low density, due to the volatility of the organic substances and alkali elements. It is well known that the standard polarization values obtained using the traditional hysteresis loops involves contributions from both the true-remanent (i.e., remanent polarization) and non-remanent (diode effects, leakage currents, etc.,) components (114, 115). To separate the non-remanent components and reveal the value of the remanent polarization  $(P_r)$ , the samples polarization response was measured after two consecutive half-triangular waves of the same polarity (114, 115). For all samples, it can be observed that the remanent P-E hysteresis loops displays a reduction in  $P_r$  and becomes squarer compared with standard polarization hysteresis loops owing to the removal of the segment caused by conduction losses and other factors. The P-E hysteresis loops of the KNNT-xLi showed similar observations. The  $P_r$  and coercive electric field ( $E_{\rm C}$ ) of all compositions are listed in Table 10. The  $P_{\rm r}$  value of the KN<sub>0.5</sub>-<sub>x</sub>Li<sub>x</sub>NT ceramics increased from 9.20 to 10.89  $\mu$ C/cm<sup>2</sup> when increasing x from 0 to 0.01 and then decreased (Table 10). The  $E_{\rm C}$  value was found in the range of 9.19-20.14 kV/cm. For the KNNT-xLi ceramics, the  $P_r$  increased to ~20.96  $\mu$ C/cm<sup>2</sup> when x went up to 0.04. The  $E_C$  of KNNT-xLi ceramics decreased from 17.78 to 10.70 kV/cm with x rising from 0 to 0.01, and then increased (Table 10). It can be observed that good remanent *P-E* hysteresis loops were found at x=0.01 for KN<sub>0.5-x</sub>Li<sub>x</sub>NT ceramics  $(P_r \sim 10.89 \ \mu \text{C/cm}^2 \text{ and } E_c \sim 13.09 \ k \text{V/cm})$  and at x=0.02 for KNNT-xLi ceramics  $(P_r \sim 15.65 \ \mu C/cm^2$  and  $E_C \sim 11.46 \ kV/cm$ ). This result can be explained by large grain sizes (Figure 68), meaning that volume fraction of grain boundary and trapped space charge at the boundaries were reduces which makes ferroelectric domain reorientation easier and continuous (116), resulting in the improvement of the remanent P-Ehysteresis loops of the samples.

Samples	То-т	Tc	$\varepsilon_{\rm R}$ tan $\delta$ $\varepsilon_{\rm C}$ tan $\delta$ Remanent <i>P</i> - <i>E</i> hysteresis					
	(°C)	(°C)		at $T_{\rm R}$		at T <sub>C</sub>	$P_{\rm r}$ ( $\mu$ C/cm <sup>2</sup> )	$E_{\rm C}$ (kV/cm)
KNNT	90	221	1372	0.23	5115	0.06	9.20	17.78
KN0.49Li0.01NT	77	234	877	0.42	3633	0.04	10.89	13.09
$KN_{0.48}Li_{0.02}NT$	-	247	1208	0.59	3540	0.05	7.03	18.89
$KN_{0.47}Li_{0.03}NT$	-	254	1441	0.41	4141	0.06	6.40	20.14
$KN_{0.46}Li_{0.04}NT$	-	266	903	0.21	3711	0.10	4.88	9.19
KNNT-0.01Li	75	233	1129	0.34	4541	0.06	13.02	10.70
KNNT-0.02Li	60	244	1155	0.32	4595	0.05	15.65	11.46
KNNT-0.03Li	/-	243	1730	0.43	4588	0.06	20.36	19.01
KNNT-0.04Li	F	253	1153	0.37	3844	0.12	20.96	20.65

Table 10 Dielectric and ferroelectric behaviors of KNNT ceramics as a functionof Li<sup>+</sup> additional and substitutional doping.



## **CHAPTER V**

## SUMMARY

First system, the effect of the firing conditions on the phase formation, microstructure, and electric properties of KNNT ceramics synthesized by the solidstate combustion method was studied. Pure KNNT powders were successfully formed after calcination at 600°C for 2 h. The average particle size increased when the calcination temperature was increased. The KNNT powder calcined at 600°C for 2 h showed rather square morphology and average particle size of  $\sim 160 nm$ , as verified by TEM. All the ceramics showed pure perovskite structure with coexisting O + Tphases, as confirmed by XRD analysis. Rietveld refinement revealed that the tetragonality increased as the dwell time was increased from 2 to 4 h. The MPB region with a 50:50 ratio of O:T was obtained for the ceramic sintered at 1150°C for 4 h. The average grain size and density values increased as the dwell time was increased from 2 to 4 h but then degraded. KNNT ceramic with good crystalline morphology, the highest density ( $\rho = 5.28 \text{ g/cm}^3$ ), the highest dielectric constant ( $\varepsilon_{\rm C} = 5002$ ), and good ferroelectric behavior ( $P_r = 18.50 \ \mu C/cm^2$  and  $E_c = 9.04 \ kV/cm$ ) was obtained when using the firing condition of 1150°C for 4 h. The results of this work suggest that the firing conditions can play an important role in increasing and improving the densification, microstructure, and dielectric and ferroelectric properties of KNNT ceramics.

The KNNT ceramics with  $Cs^+$  substitutional (K<sub>0.5-x</sub>Cs<sub>x</sub>NNT) and additional (KNNT-xCs) doping at x=0, 0.01, 0.02, 0.03 and 0.04 mol.% were synthesized by the solid-state combustion technique. The phase evolution, microstructure, dielectric and ferroelectric properties of the ceramics were investigated. All ceramics revealed a pure perovskite structure with coexisting *O*+*T* phases. Increasing both the amount of Cs<sup>+</sup> substitutional and additional doping enhanced the content of orthorhombic phase, as verified by the Rietveld refinement technique. It has been demonstrated that Cs<sup>+</sup> doping, either substitutional or additional, strongly decreased the density, dielectric and ferroelectric properties. The undoped KNNT ceramic showed a well-saturated *P*-

*E* hysteresis loop, while it became unsaturated and a leakage current was generated with  $Cs^+$  doping. The KNNT-xCs ceramics demonstrated a higher density and dielectric properties than the  $K_{0.5-x}Cs_xNNT$  ceramics. The deterioration in the dielectric and ferroelectric properties of the ceramics was mainly due to the inferior microstructure and low density induced by  $Cs^+$  doping. The results of the phase evolution, microstructure, density, and electrical properties are all in agreement with each other.

For, a system of KNNT ceramics with Li<sup>+</sup> substitution (KN<sub>0.5-x</sub>Li<sub>x</sub>NT) and direct (KNNT-xLi) doping at x=0, 0.01, 0.02, 0.03 and 0.04 mol.% were fabricated via the solid-state combustion route. The phase structure, microstructure, dielectric, and ferroelectric properties of the specimens were inspected. The XRD results disclosed that all samples had coexisting orthorhombic and tetragonal phases. With increasing Li<sup>+</sup> doping, the content of the tetragonal phase of the ceramics was enhanced, as verified by the Rietveld refinement procedure. The density of both the KN<sub>0.5-x</sub>Li<sub>x</sub>NT and KNNT-xLi ceramics decreased with rising x. The Curie temperature  $(T_{\rm C})$  of both KN<sub>0.5-x</sub>Li<sub>x</sub>NT and KNNT-xLi ceramics shifted to higher temperatures with increasing x, due to increased tetragonal distortion, whereas the dielectric constant ( $\varepsilon_{\rm C}$ ) decreased. The worsening of the dielectric properties of the ceramics was affected by the increase of the defect concentration and low density, due to the volatilization of the alkali components. The  $KN_{0.5-x}Li_xNT$  ceramics with x=0.01 showed good remanent *P*-*E* hysteresis loops ( $P_r \sim 10.89 \ \mu C/cm^2$  and  $E_C \sim 13.09 \ kV/cm$ ), while for KNNT-xLi ceramics, with the best results were with x=0.02 (Pr~15.65  $\mu$ C/cm<sup>2</sup> and E<sub>C</sub>~11.46 kV/cm). All the results derived in this research are consistent with each other.

In summary, the deterioration in electrical properties of KNNT ceramics with  $Cs^+$  and  $Li^+$  substitution and direct doping can be attributed to the inappropriate *O*:*T* phase ratio, low density and increase of the defect concentration in specimens.

We also studied the effect of ion radius on phase evolution, density and electric behaviors of KNNT ceramics. It can be concluded that the doping with Cs<sup>+</sup> at larger ion radius (1.88 Å) into K<sup>+</sup> (1.64 Å) and Na<sup>+</sup> (1.39 Å) at A-site of KNNT ceramics increased the orthorhombic phase, whereas doping with Li<sup>+</sup> (1.15 Å) at smaller ion radius into K<sup>+</sup> and Na<sup>+</sup> at A-site rise the tetragonal phase. However, the

results of density and electric behaviors for both  $Cs^+$  and  $Li^+$  doping into KNNT ceramics lead to the similar trend, i.e., declining.



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<ul> <li>Education Background</li> <li>2015 B.Sc. (Applied Physics) Naresuan University</li> <li>2017 M.Sc. (Applied Physics) Naresuan University</li> <li>2022 Ph.D. (Applied Physics) Naresuan University</li> <li>2022 Ph.D. (Applied Physics) Naresuan University</li> <li>1. Yotthuan S, Janlong N, Pinitsoontorn S, Suriwong T,</li> <li>Wongdammern N, Udeye T, Bongkarn T. Phase formation,</li> <li>microstructure, electric and magnetic properties of NiO</li> <li>doping in (Ba0.85Ca0.15)(Ti0.90Zr0.10)O3 ceramics.</li> <li>Integr. Ferroelectr. 2022;222(1):149-162.</li> <li>2. Sinkruason T, Thawong P, Yotthuan S, Jutimoosik J,</li> <li>Bongkarn T. Effect of Fe2O3 Doping on Phase Formation,</li> <li>Microstructure, Dielectric and Magnetic Properties of</li> <li>BNT-BKT-KNN Ceramics Prepared by the Solid-State</li> <li>Combustion Technique. Integr. Ferroelectr.</li> <li>2021;223(1):196-205.</li> <li>3. Yotthuan S, Udeye T, Vittayakorn N, Pulphol P,</li> <li>Bongkarn T. The influences of Cs+ substitution and direct</li> <li>doping on the phase evolution, microstructure and</li> <li>electrical properties of KNNT ceramics. Ferroelectrics.</li> <li>2021;238(1):133-146.</li> <li>4. Komphom C, Yotthuan S, Kidkhunthod P, Bongkarn T.</li> <li>Stabilization of the morphotropic phase boundary in (1-x)BNT-xBCTS ceramics prepared by the solid-state</li> <li>combustion technique. Radiat. Phys. Chem.</li> <li>2021;188(1):109638-10.</li> <li>5. Yotthuan S, Rueanngam S, Pinitsoontorn S, Chootin S,</li> <li>Bongkarn T. The phase structure, microstructure, dielectric and magnetic properties of</li> <li>0.99(K0.45Na0.52Li0.03)(Nb0.94Sb0.06)O3-0.01BiScO3</li> <li>ceramics with NiO doping. Integr. Ferroelectr.</li> <li>2021;214(1):56-68.</li> <li>6. Yotthuan S, Charoonsuk T, Vittayakorn N, Thountom S,</li> <li>Suriwong T, Udeye T, Bongkarn T. Effect of firing conditions on phase formation, microstructure, and</li> <li>electrical properties of (K0.5Na0.5)(Nb0.7Ta0.3)O3</li> </ul>	Address	1/1 No. 3, Ban Na Sub-district, Wachirabarami District, Phichit Province, 66140					
<ul> <li>Publication</li> <li>2022 Ph.D. (Applied Physics) Naresuan University</li> <li>1. Yothuan S, Janlong N, Pinitsoontorn S, Suriwong T, Wongdamnern N, Udeye T, Bongkarn T. Phase formation, microstructure, electric and magnetic properties of NiO doping in (Ba0.85Ca0.15)(Ti0.90Zr0.10)O3 ceramics. Integr. Ferroelectr. 2022;222(1):149-162.</li> <li>2. Sinkruason T, Thawong P, Yotthuan S, Jutimoosik J, Bongkarn T. Effect of Fe2O3 Doping on Phase Formation, Microstructure, Dielectric and Magnetic Properties of BNT-BKT-KNN Ceramics Prepared by the Solid-State Combustion Technique. Integr. Ferroelectr. 2021;223(1):196-205.</li> <li>3. Yotthuan S, Udeye T, Vittayakorn N, Pulphol P, Bongkarn T. The influences of Cs+ substitution and direct doping on the phase evolution, microstructure and electrical properties of KNNT ceramics. Ferroelectrics. 2021;586(1):133-146.</li> <li>4. Kornphom C, Yotthuan S, Kidkhunthod P, Bongkarn T. Stabilization of the morphotropic phase boundary in (1-x)BNT-xBCTS ceramics prepared by the solid-state combustion technique. Radiat. Phys. Chem. 2021;188(1):109638-10.</li> <li>5. Yotthuan S, Rueanngam S, Pinitsoontorn S, Chootin S, Bongkarn T. The phase structure, microstructure, dielectric and magnetic properties of 0.99(K0.45Na0.52Li0.03)(Nb0.94Sb0.06)O3-0.01BiScO3 ceramics with NiO doping. Integr. Ferroelectr. 2021;214(1):56-68.</li> <li>6. Yotthuan S, Charoonsuk T, Vittayakorn N, Thountom S, Suriwong T, Udeye T, Bongkarn T. Effect of firing conditions on phase formation, microstructure, and electrical properties of (K0.5Na0.5)(Nb0.7Ta0.3)O3</li> </ul>	Education Background	2015 B.Sc. (Applied Physics) Naresuan University 2017 M.Sc. (Applied Physics) Naresuan University					
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